

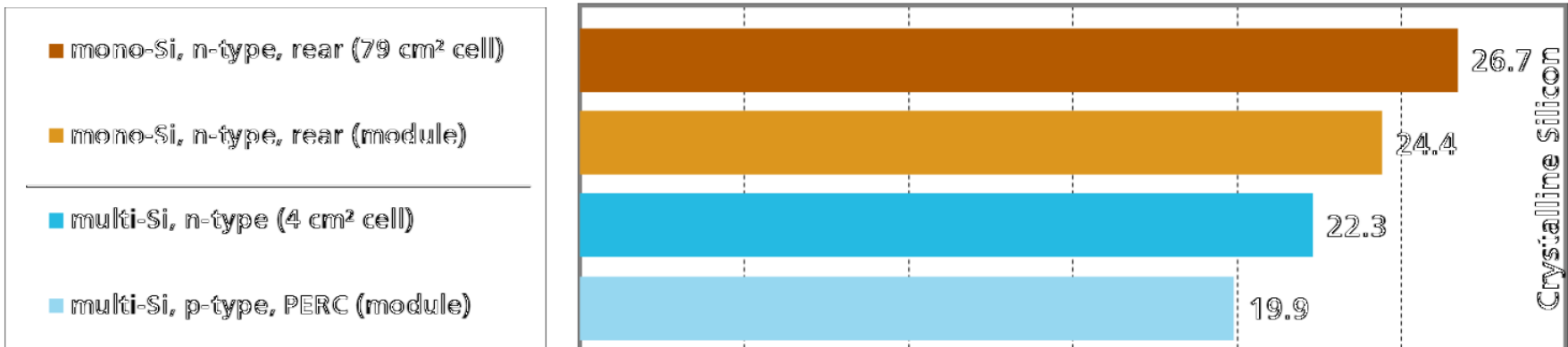
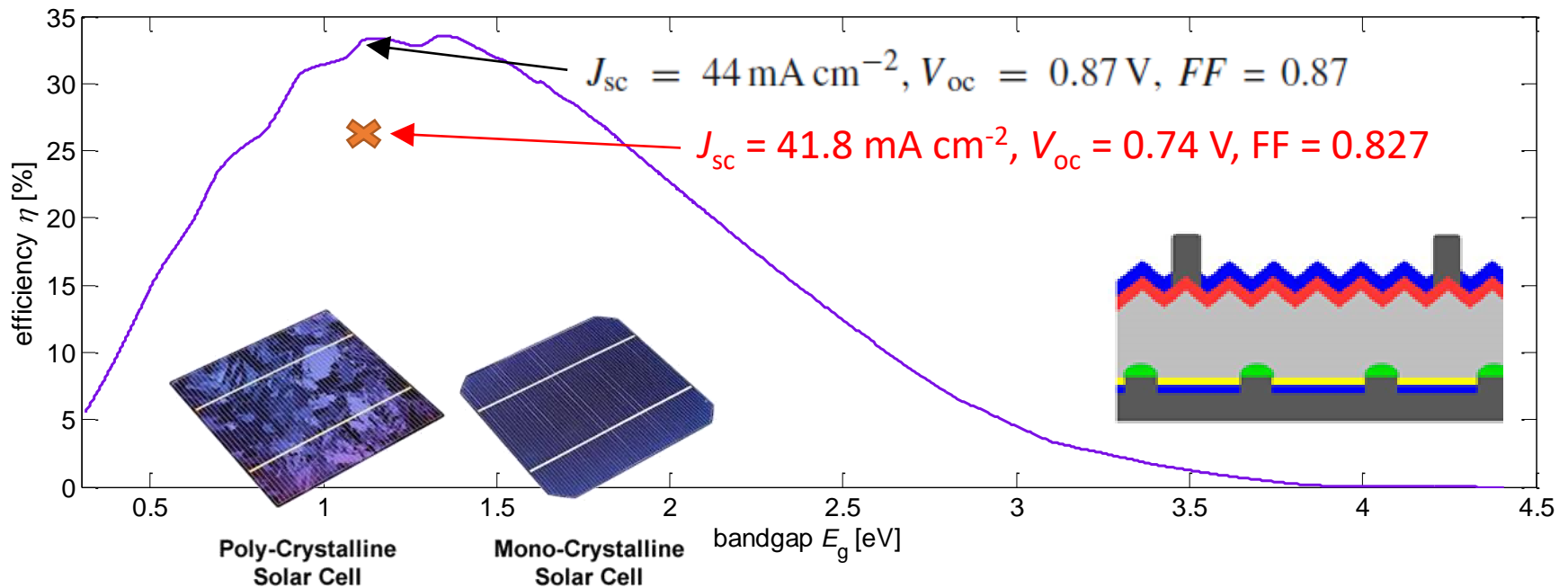
Solar Photovoltaics & Energy Systems

Lecture 4. III-V, Thin Film, and Organic Solar Cells

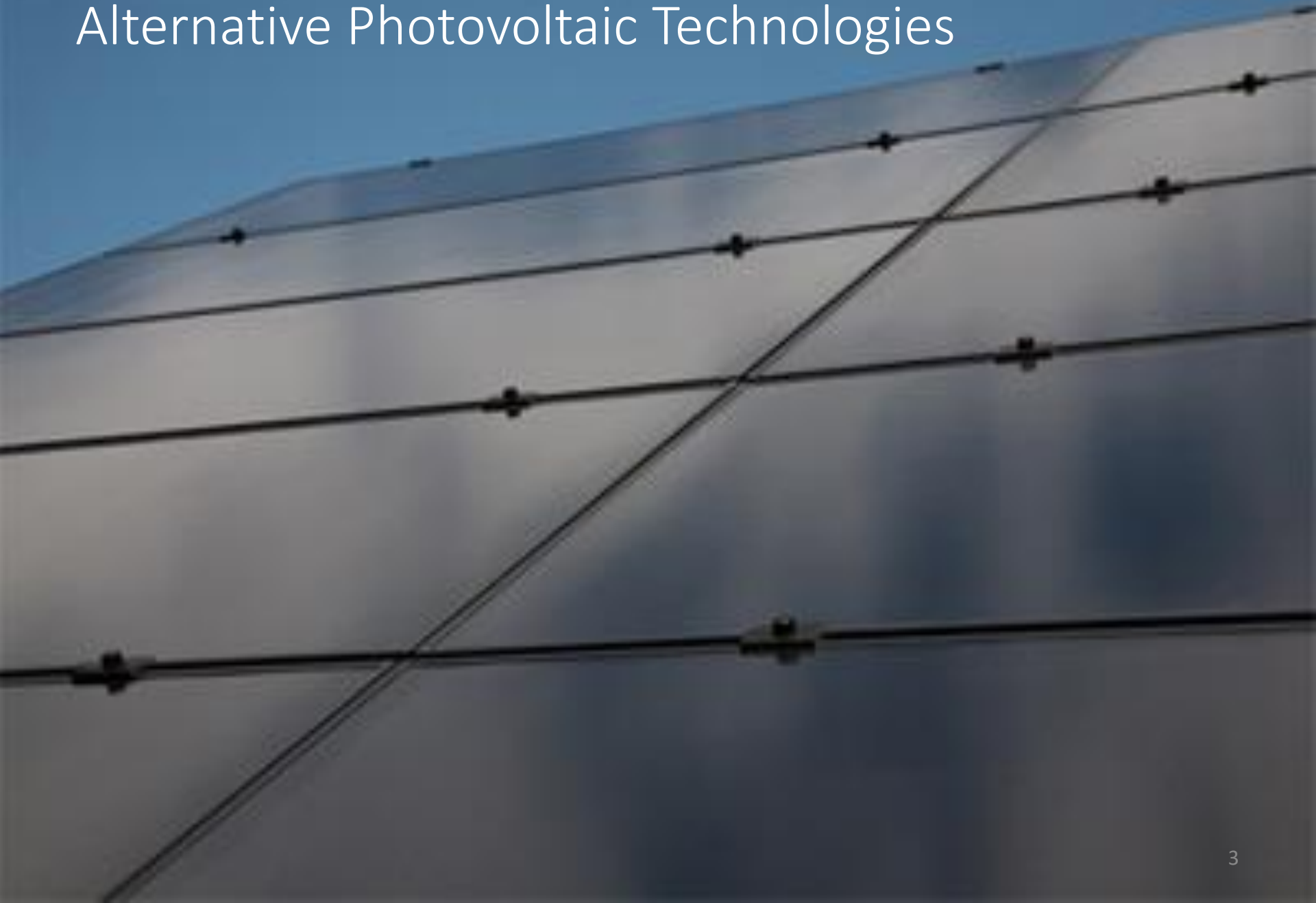
ChE-600

Wolfgang Tress, March 2018

Summary Crystalline Silicon Solar Cells



Alternative Photovoltaic Technologies

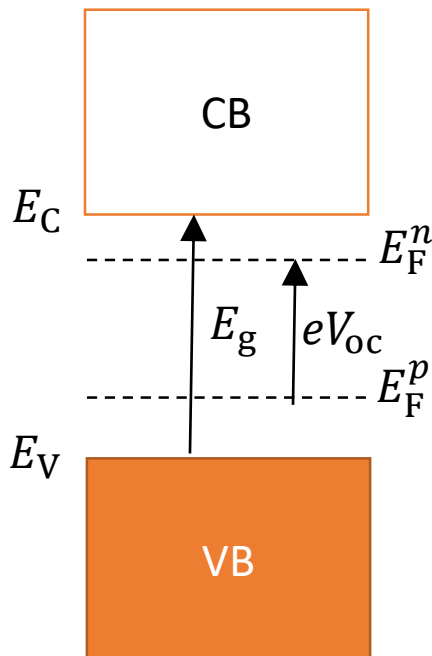


- Can we do better than Silicon?
- Can we do cheaper than Silicon?
- Can we do more than Silicon?

The Open Circuit Voltage

- Ideally:
$$V_{oc,rad} = \frac{k_B T}{e} \ln \left(\frac{J_{ph}}{J_{em,0}} + 1 \right)$$

- Alternative expression:
$$V_{oc} = \frac{E_F^n - E_F^p}{e} = \frac{E_g}{e} - \frac{k_B T}{e} \ln \left(\frac{N_C N_V}{np} \right)$$



$$n = N_C \exp \left(-\frac{E_C - E_F^n}{k_B T} \right)$$

$$p = N_V \exp \left(-\frac{E_F^p - E_V}{k_B T} \right)$$

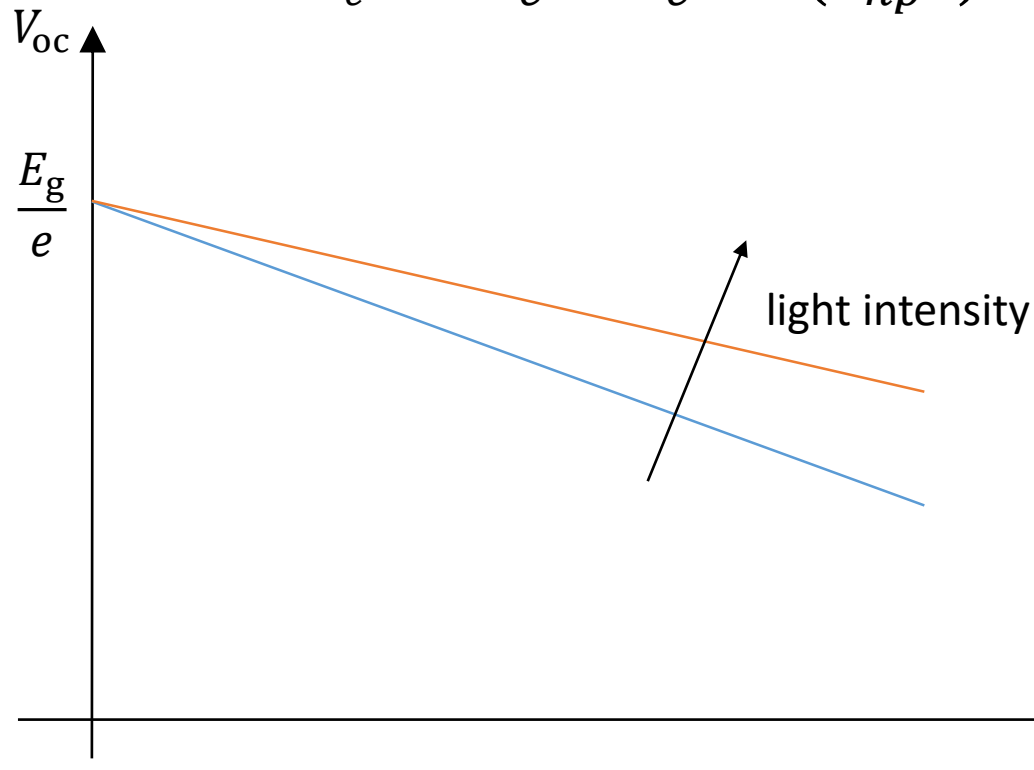
band gap

temperature

recombination
light intensity

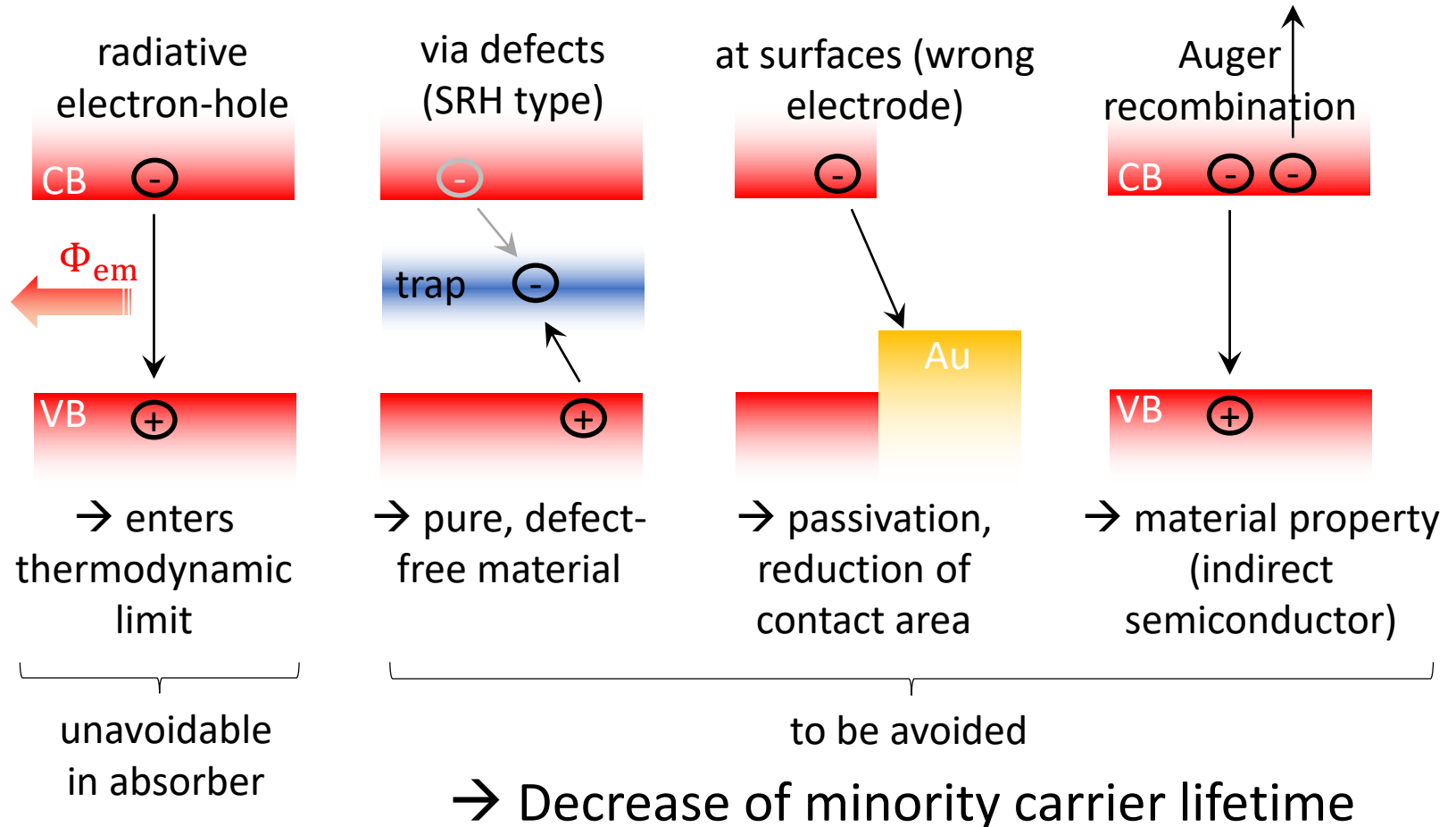
Increasing the Open Circuit Voltage

$$V_{oc} = \frac{E_F^n - E_F^p}{e} = \frac{E_g}{e} - \frac{k_B T}{e} \ln \left(\frac{N_C N_V}{np} \right)$$

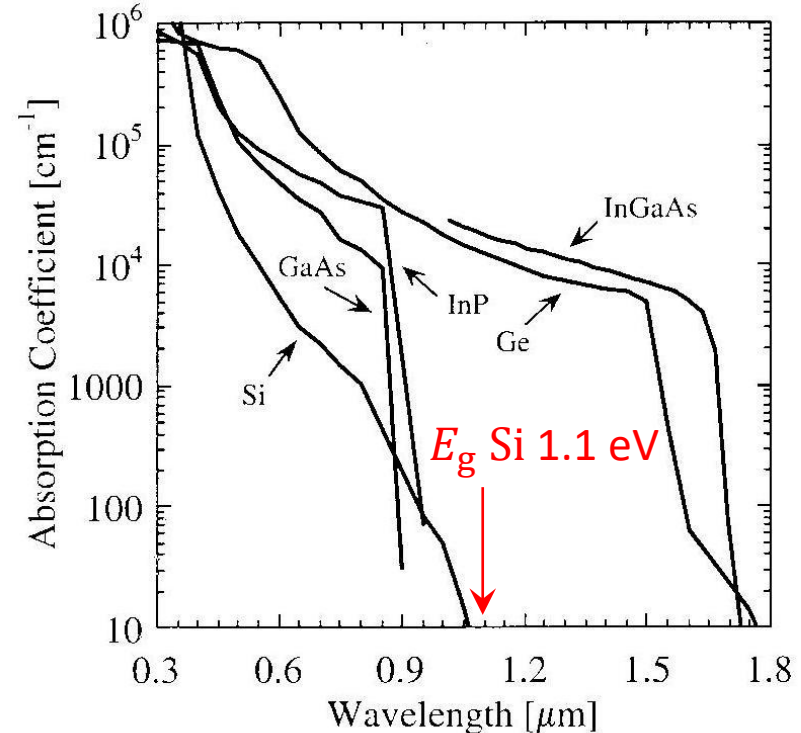
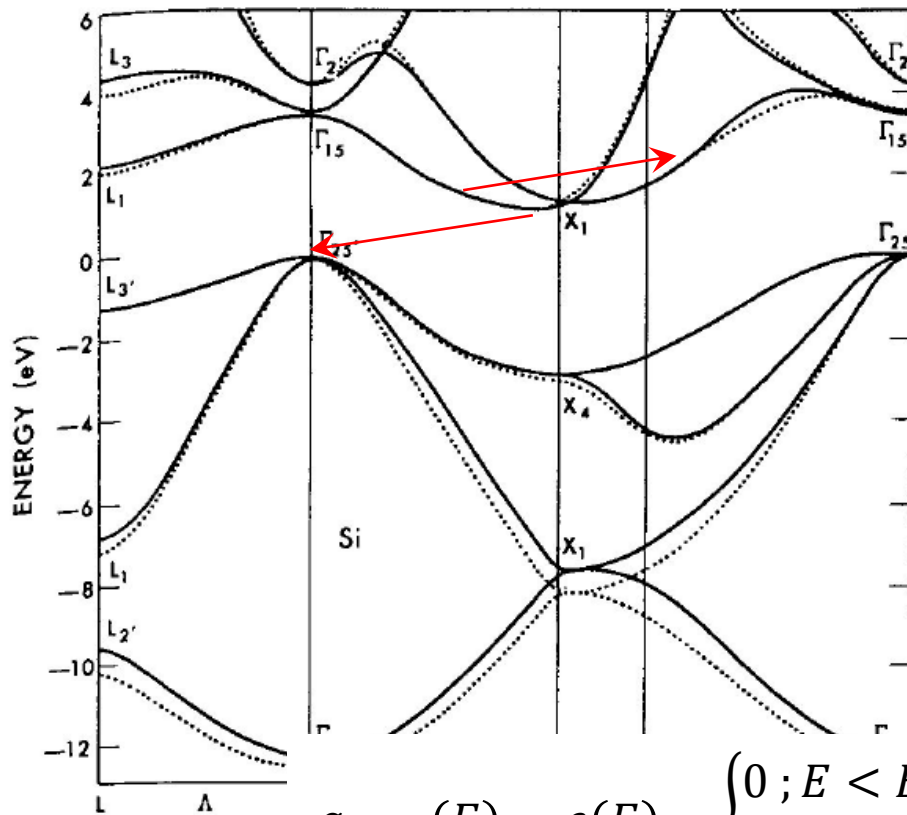


→ Cooling, concentration, high absorption, light trapping
(thinner layers)

Recombination



Si is an Indirect Semiconductor



Handbook of Optical Constants of Solids, edited by Edward D. Palik, (1985), Academic Press NY.

$$a_{\text{ideal}}(E) = e(E) = \begin{cases} 0 & ; E < E_g \\ 1 & ; E \geq E_g \end{cases} \quad a_{\text{real}}(E) = 1 - r(E) - \exp(-ad)$$

- Conservation of energy and momentum \rightarrow Auger recombination
- Indirect transition \rightarrow low absorption coefficient at E_g

III-V Semiconductors: GaAs

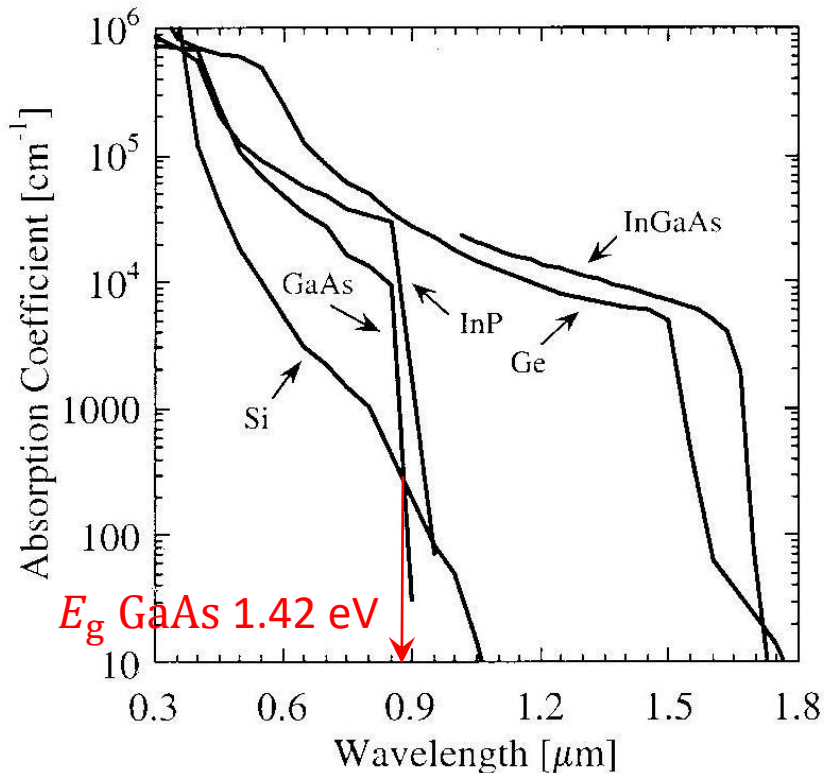
Periodic Table of the Elements

1 IA 1A																	18 VIIIA 8A
1 H Hydrogen 1.008	2 IIA 2A											13 IIIA 3A	14 IVA 4A	15 VA 5A	16 VIA 6A	17 VIIA 7A	2 He Helium 4.003
3 Li Lithium 6.941	4 Be Beryllium 9.012											5 B Boron 10.811	6 C Carbon 12.011	7 N Nitrogen 14.007	8 O Oxygen 15.999	9 F Fluorine 18.998	10 Ne Neon 20.180
11 Na Sodium 22.990	12 Mg Magnesium 24.305	3 IIIB 3B	4 IVB 4B	5 VB 5B	6 VIB 6B	7 VIIB 7B	8 VIII 8	9 VIII 8	10 VIII 8	11 IB 1B	12 IIB 2B	13 Al Aluminum 26.982	14 Si Silicon 28.086	15 P Phosphorus 30.974	16 S Sulfur 32.066	17 Cl Chlorine 35.453	18 Ar Argon 39.948
19 K Potassium 39.098	20 Ca Calcium 40.078	21 Sc Scandium 44.956	22 Ti Titanium 47.867	23 V Vanadium 50.942	24 Cr Chromium 51.996	25 Mn Manganese 54.938	26 Fe Iron 55.845	27 Co Cobalt 58.933	28 Ni Nickel 58.693	29 Cu Copper 63.546	30 Zn Zinc 65.38	31 Ga Gallium 69.723	32 Ge Germanium 72.631	33 As Arsenic 74.922	34 Se Selenium 78.972	35 Br Bromine 79.904	36 Kr Krypton 84.798
37 Rb Rubidium 85.468	38 Sr Strontium 87.62	39 Y Yttrium 88.906	40 Zr Zirconium 91.224	41 Nb Niobium 92.906	42 Mo Molybdenum 95.95	43 Tc Technetium 98.907	44 Ru Ruthenium 101.07	45 Rh Rhodium 102.906	46 Pd Palladium 106.42	47 Ag Silver 107.868	48 Cd Cadmium 112.411	49 In Indium 114.818	50 Sn Tin 118.711	51 Sb Antimony 121.760	52 Te Tellurium 127.6	53 I Iodine 126.904	54 Xe Xenon 131.294
55 Cs Cesium 132.905	56 Ba Barium 137.328	57-71	72 Hf Hafnium 178.49	73 Ta Tantalum 180.948	74 W Tungsten 183.84	75 Re Rhenium 186.207	76 Os Osmium 190.23	77 Ir Iridium 192.217	78 Pt Platinum 195.085	79 Au Gold 196.967	80 Hg Mercury 200.592	81 Tl Thallium 204.383	82 Pb Lead 207.2	83 Bi Bismuth 208.980	84 Po Polonium [208.982]	85 At Astatine 209.987	86 Rn Radon 222.018
87 Fr Francium 223.020	88 Ra Radium 226.025	89-103	104 Rf Rutherfordium [261]	105 Db Dubnium [262]	106 Sg Seaborgium [266]	107 Bh Bohrium [264]	108 Hs Hassium [269]	109 Mt Meitnerium [268]	110 Ds Darmstadtium [269]	111 Rg Roentgenium [272]	112 Cn Copernicium [277]	113 Uut Ununtrium unknown	114 Fl Flerovium [289]	115 Uup Ununpentium unknown	116 Lv Livermorium [298]	117 Uus Ununseptium unknown	118 Uuo Ununoctium unknown

Lanthanide Series	57 La Lanthanum 138.905	58 Ce Cerium 140.116	59 Pr Praseodymium 140.908	60 Nd Neodymium 144.242	61 Pm Promethium 144.913	62 Sm Samarium 150.36	63 Eu Europium 151.964	64 Gd Gadolinium 157.25	65 Tb Terbium 158.925	66 Dy Dysprosium 162.500	67 Ho Holmium 164.930	68 Er Erbium 167.259	69 Tm Thulium 168.934	70 Yb Ytterbium 173.055	71 Lu Lutetium 174.967
Actinide Series	89 Ac Actinium 227.028	90 Th Thorium 232.038	91 Pa Protactinium 231.036	92 U Uranium 238.029	93 Np Neptunium 237.048	94 Pu Plutonium 244.064	95 Am Americium 243.061	96 Cm Curium 247.070	97 Bk Berkelium 247.070	98 Cf Californium 251.080	99 Es Einsteinium [254]	100 Fm Fermium 257.095	101 Md Mendelevium 258.1	102 No Nobelium 259.101	103 Lr Lawrencium [262]

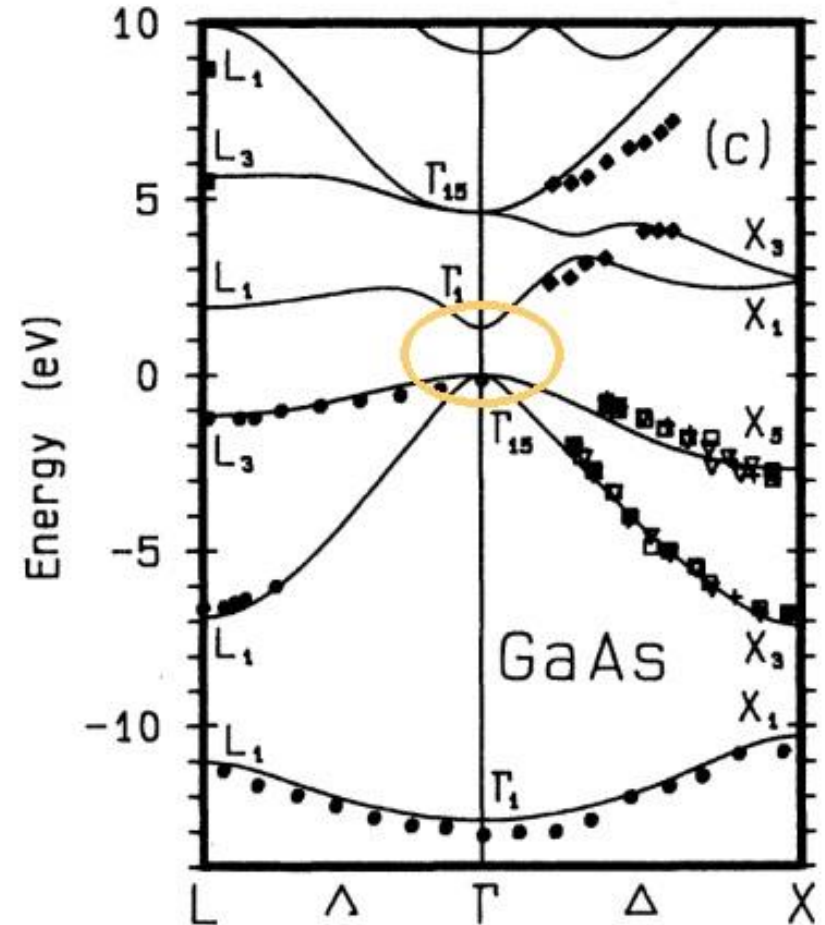
Alkali Metal	Alkaline Earth	Transition Metal	Basic Metal	Semimetal	Nonmetal	Halogen	Noble Gas	Lanthanide	Actinide
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III-V Semiconductors: GaAs



Handbook of Optical Constants of Solids, edited by Edward D. Palik, (1985), Academic Press NY.

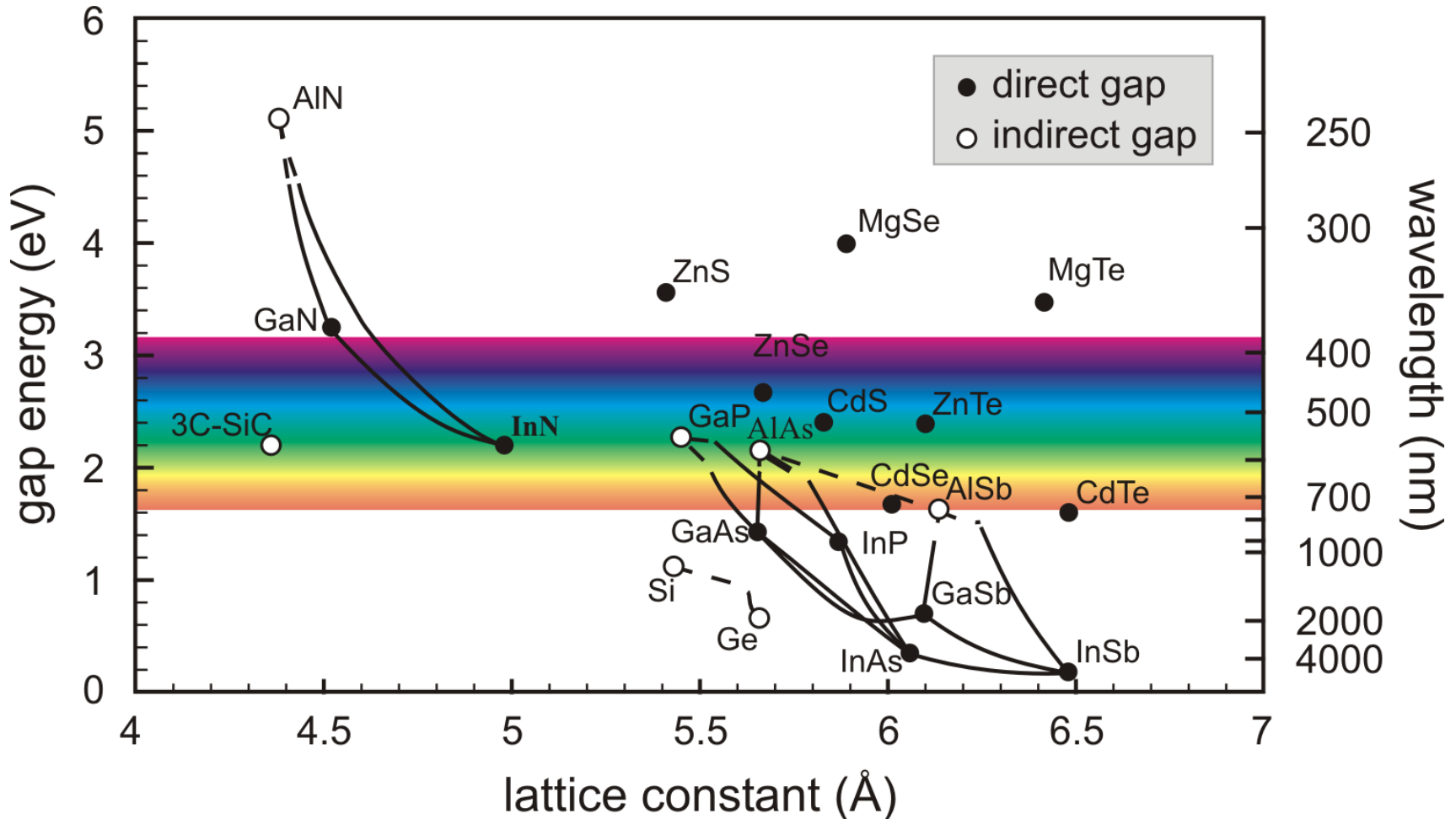
→ $\eta = 28 \%$ reached



Michael Rohlfling, Peter Krüger, and Johannes Pollmann: *Quasiparticle band-structure calculations for C, Si, Ge, GaAs, and SiC using Gaussian-orbital basis sets*, Phys. Rev. **B48** (1993) 17791-17805 (doi: [10.1103/PhysRevB.48.17791](https://doi.org/10.1103/PhysRevB.48.17791)), Fig. 3.

III-V SC: Band Gap Engineering

http://gorgia.no-ip.com/phd/html/thesis/phd_html/node4.html



III-V SC: Multi Junction Solar Cells

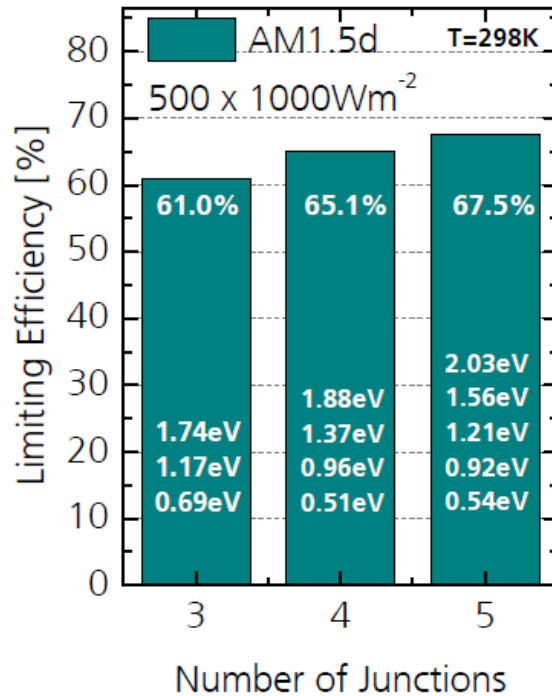


Figure 1: Detailed balanced limit calculations for 3J, 4J and 5J MJ cells under concentrated light, with the optimum bandgap combination shown [5].

ISE, Freiburg Presented at the 29th European PV Solar Energy Conference and Exhibition, 22-26 September 2014, Amsterdam, The Netherlands

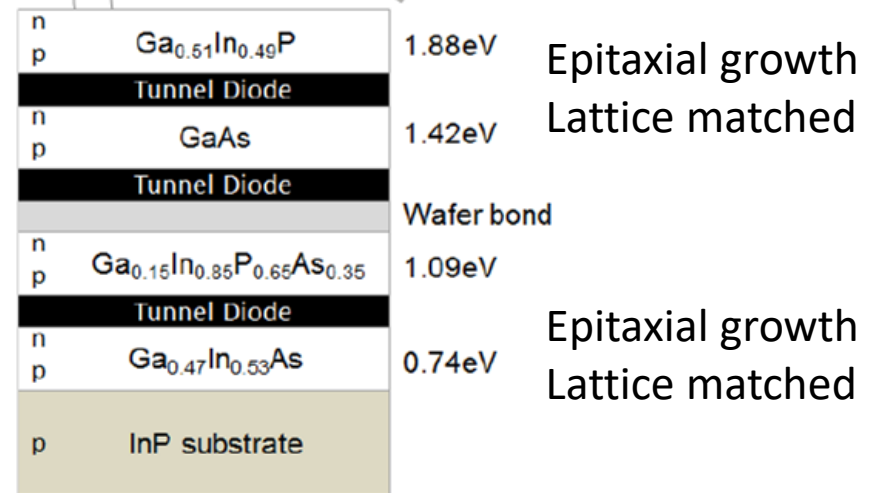
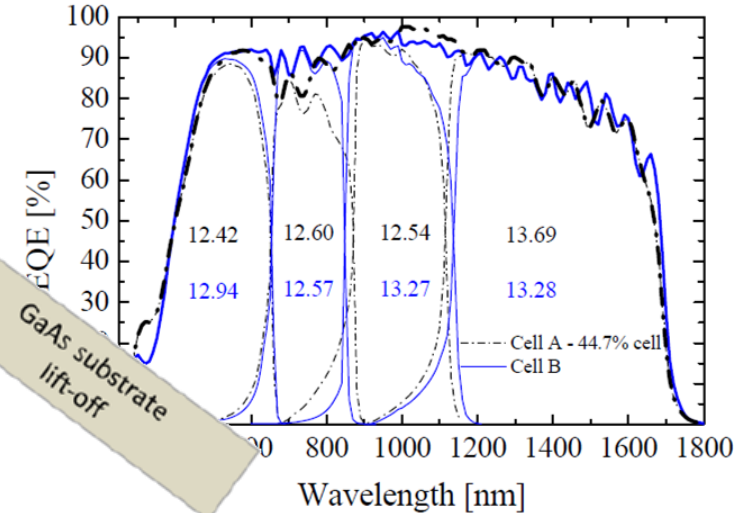
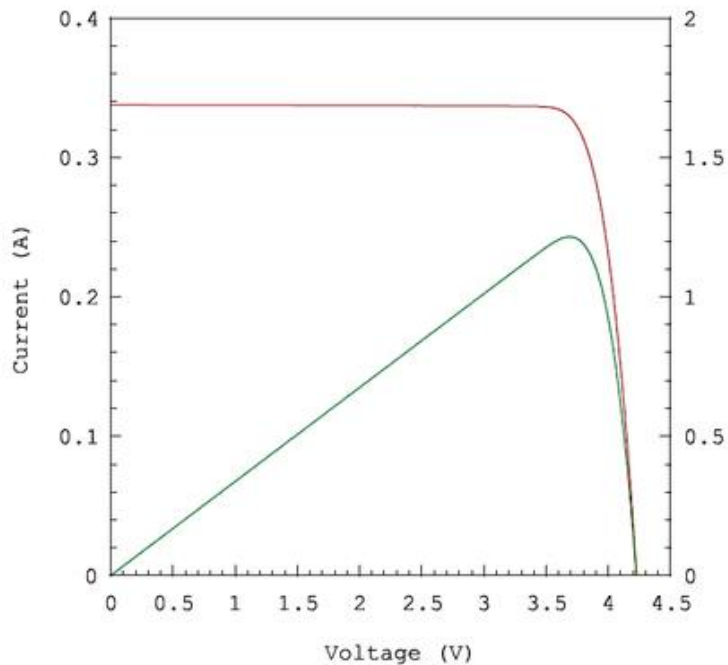


Figure 2: Schematic of a wafer-bonded GaInP/GaAs//GaInPAs/GaInAs 4J solar cell.

III-V SC: Multi Junction Solar Cells

I-V CURVE
ASTM E927-10 0.0520cm² (designated area) T-HIPSS



Date : 8 Oct 2014
Data No :
lot21-03-x19y04-01
Sample No :
lot21-03-x19y04
Repeat Times : 9

Isc	337.9	mA
Voc	4.227	V
Pmax	1.215	W
Ipmax	329.8	mA
Vpmax	3.686	V
F.F.	85.1	%
Eff (da)	46.0	%
DTemp.	25.0	°C
MTemp.	24.6	°C
DIrr.	50.8	W/cm ²
MIrr.	50.9	W/cm ² (1st)
	50.8	W/cm ² (2nd)
	50.0	W/cm ² (3rd)
	50.9	W/cm ² (4th)

Scan Mode
Weighted average of
(Isc to Voc) and
(Voc to Isc)



→ World record four-junction solar cell $\eta = 46\%$

Multi Junction Concentrator Solar Cells



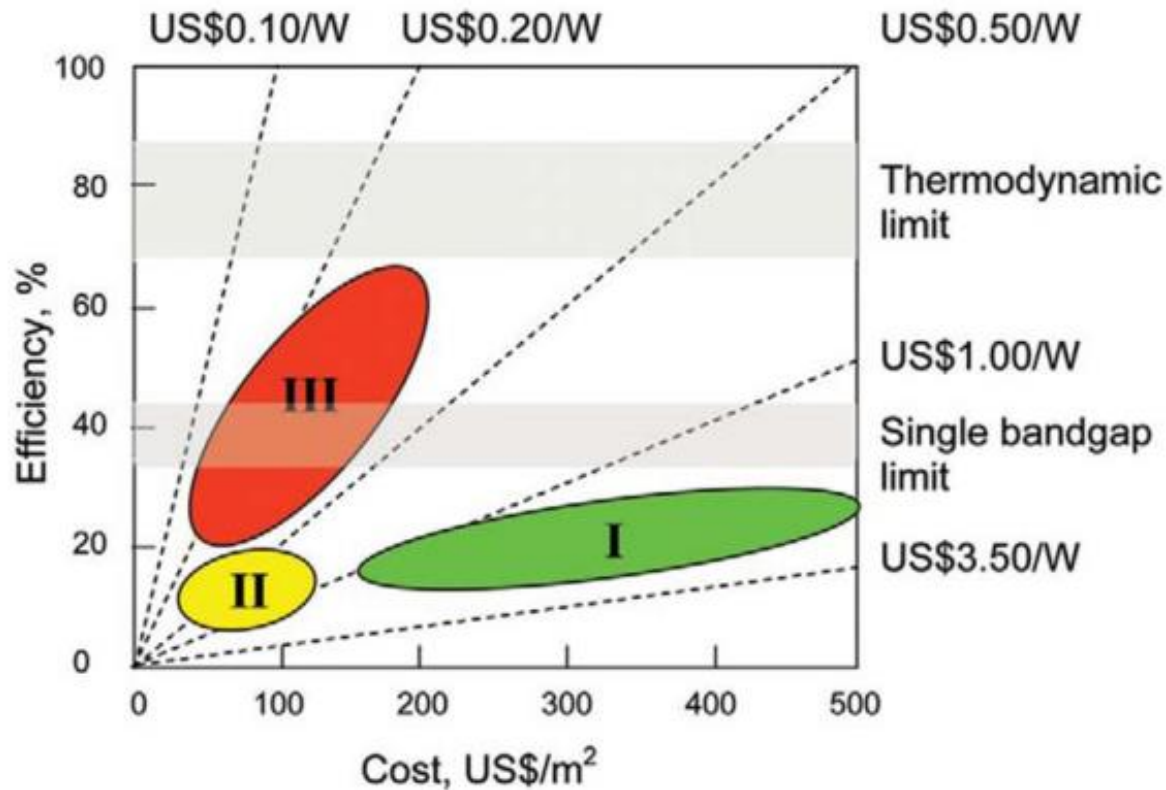
- 500 x concentration
- Cooling
- Direct light
- Sun tracking

Generations of Solar Cells

Tinted areas:

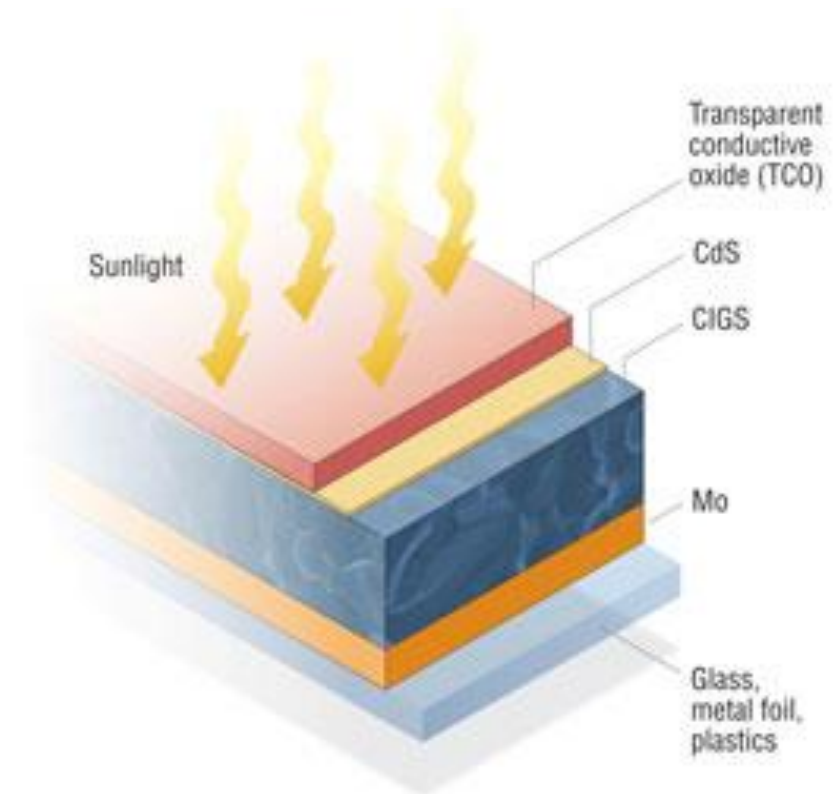
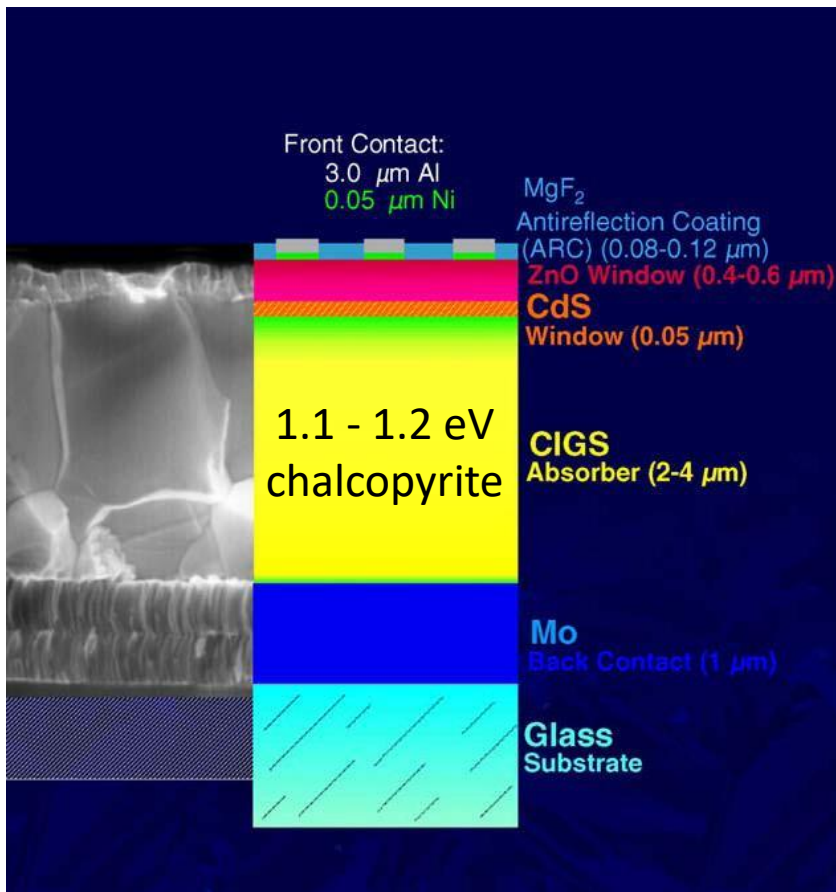
67 - 87% representing thermodynamic limit

31 - 41% representing single bandgap limit



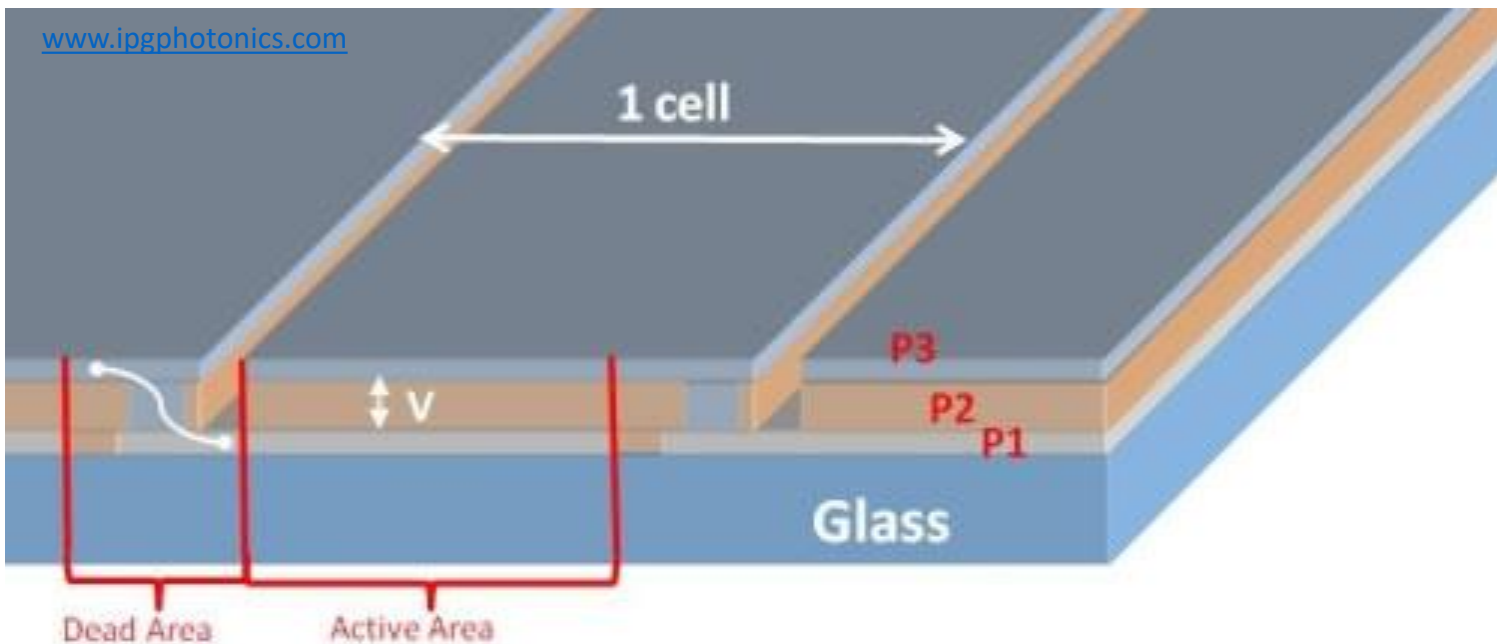
Thin Film Solar Cells: CIGS

- Alloying of CIS (CuInSe_2) with CGS (CuGaSe_2) to tune band gap

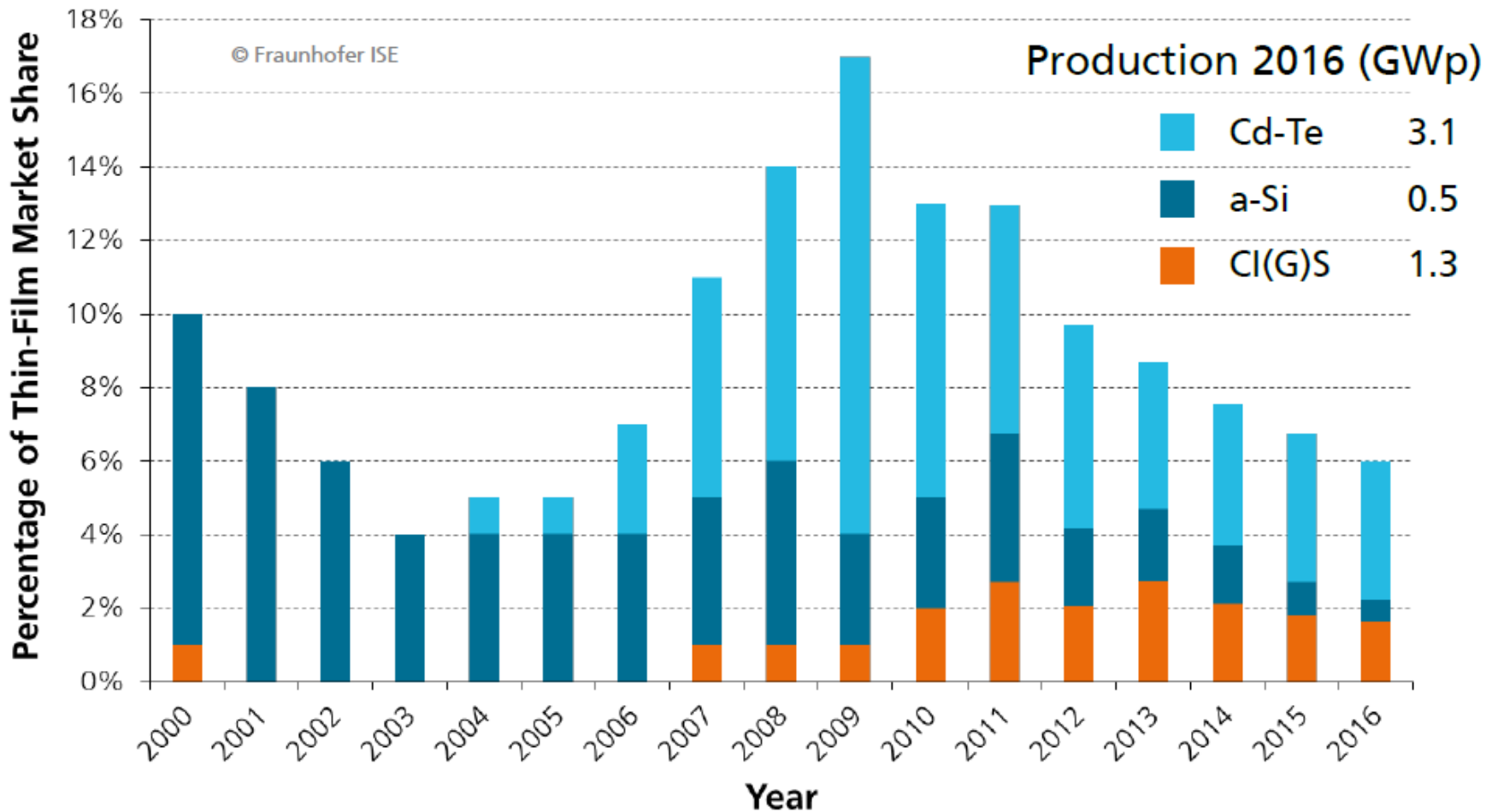


Thin Film Solar Cells: Module

Glass substrate → thin film deposition → laser scribing → series connection of stripes

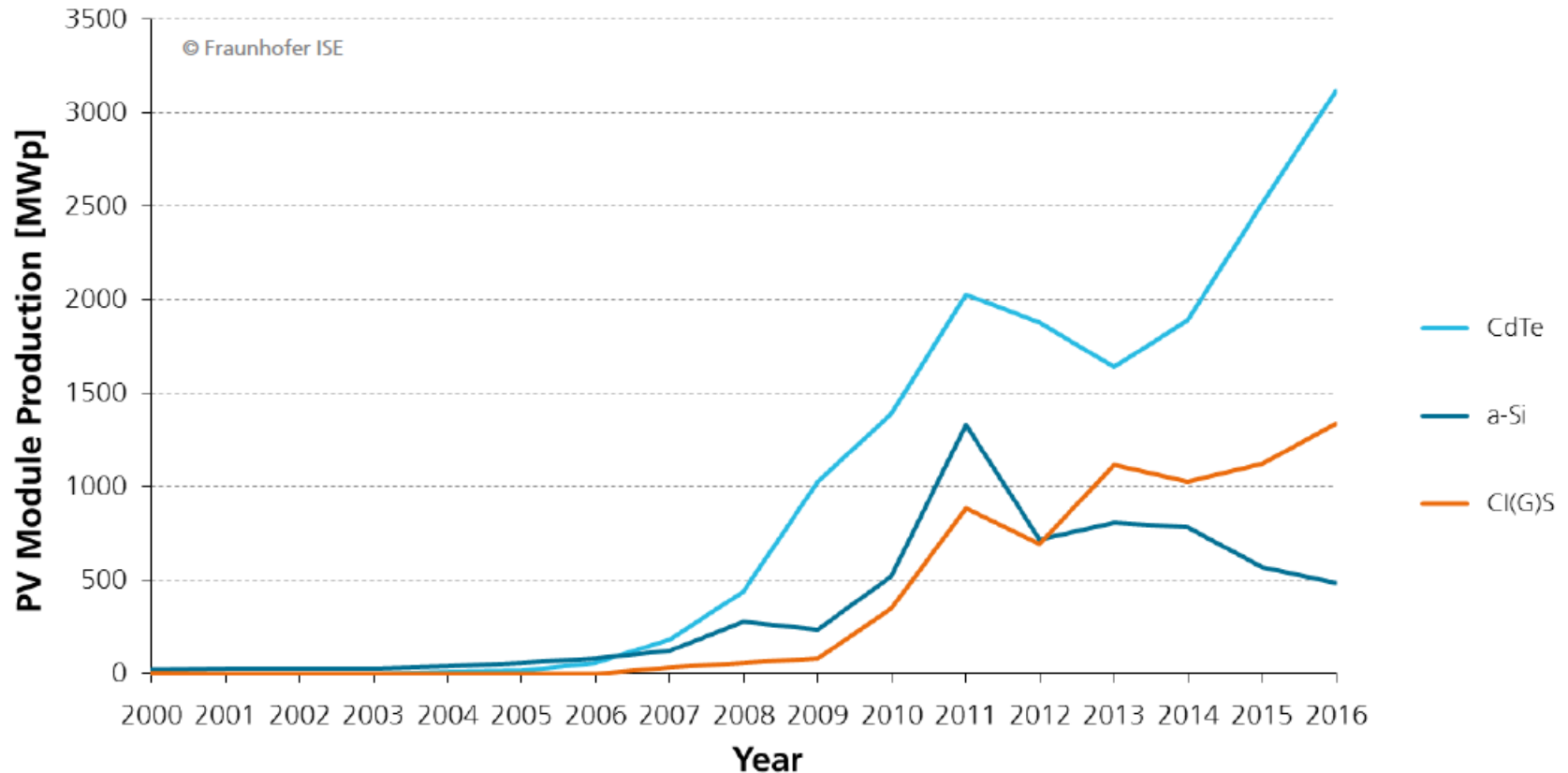


Thin Film Solar Cells: Market Share



Data: from 2000 to 2010: Navigant; from 2011: IHS. Graph: PSE 2017

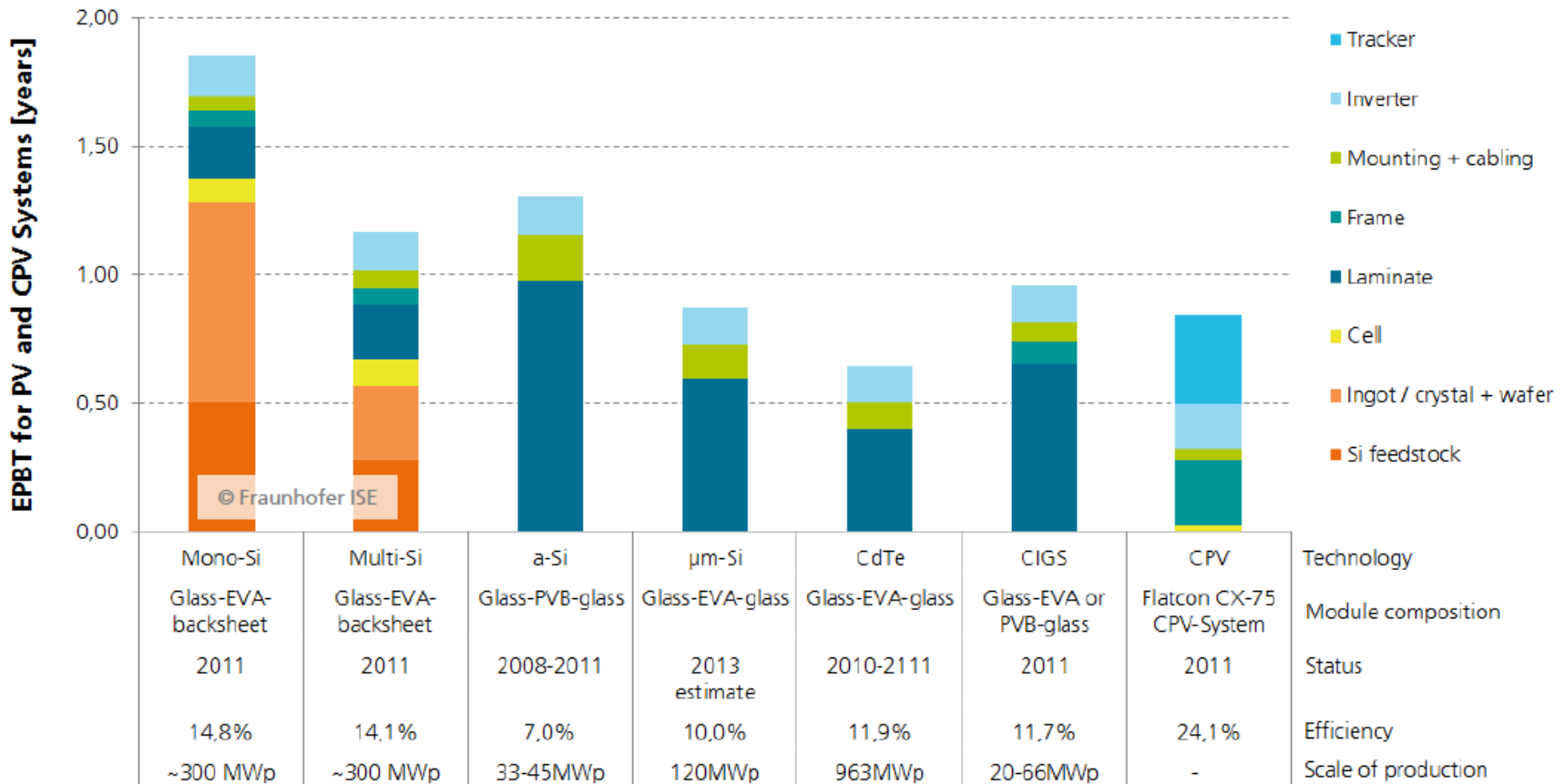
Thin Film Solar Cells: Production



Data: from 2000 to 2010: Navigant; from 2011: IHS. Graph: PSE 2017

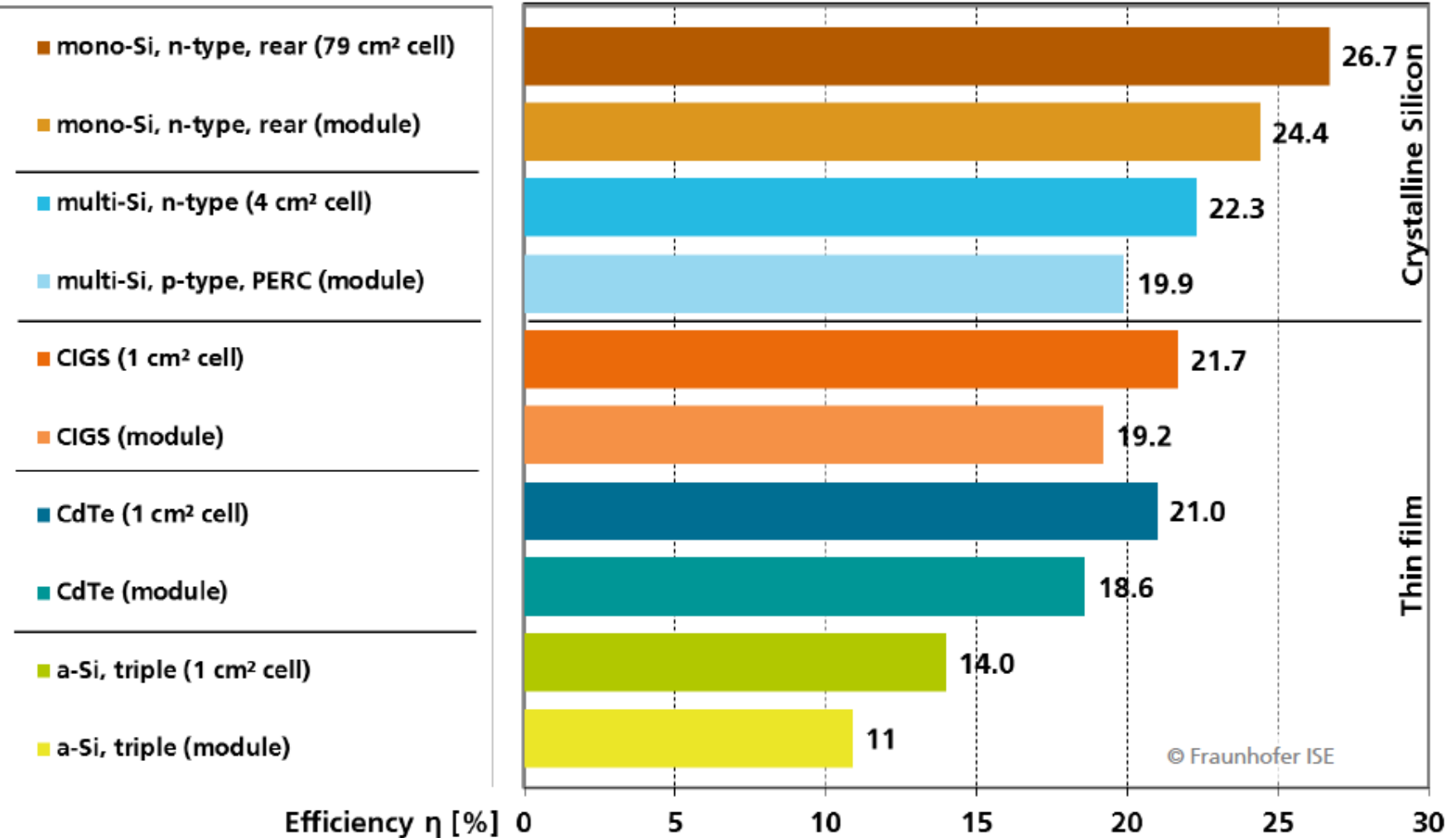
Energy Payback Time (EPBT)

Global Irrad.: 1925 kWh/m²/yr, Direct Normal Irrad.: 1794 kWh/m²/yr



Data: M.J. de Wild-Scholten 2013; CPV data: "Environmental Sustainability of Concentrator PV Systems: Preliminary LCA Results of the Apollon Project" 5th World Conference on PV Energy Conversion. Valencia, Spain, 6-10 September 2010. Graph: PSE 2014

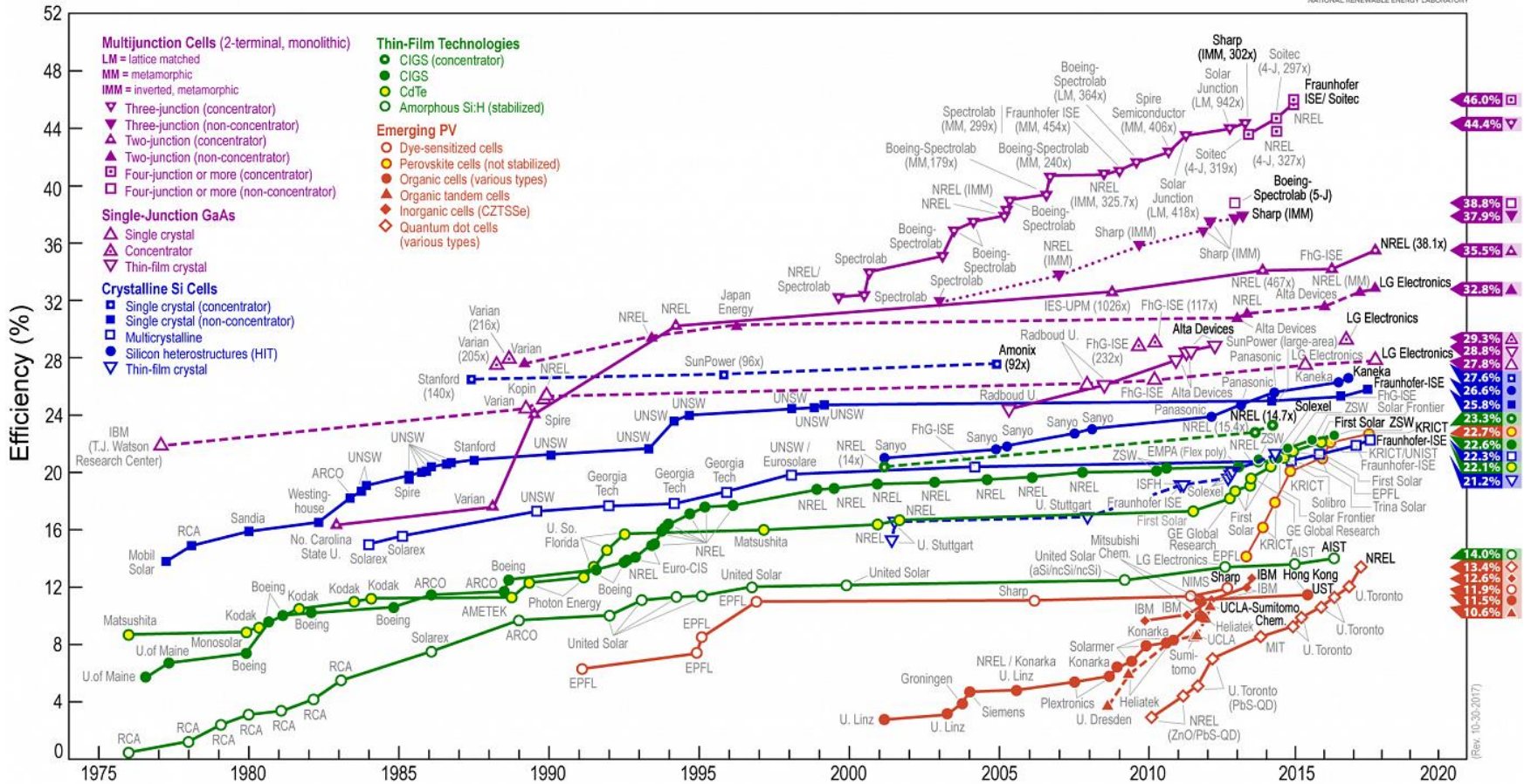
Record Efficiencies



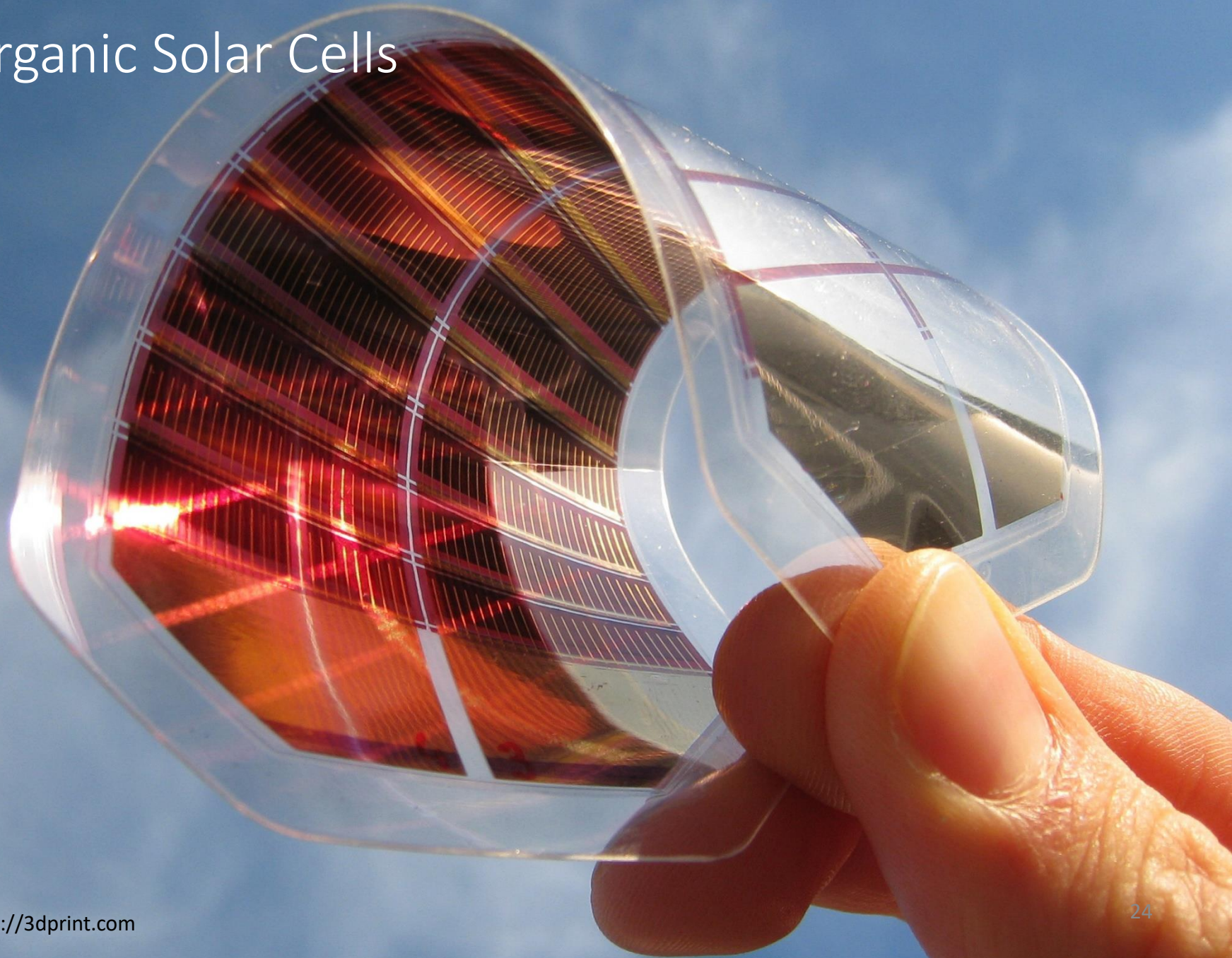
Data: Green et al.: Solar Cell Efficiency Tables (Version 51), Progress in PV: Research and Applications 2018. Graph: PSE 2018

NREL Chart

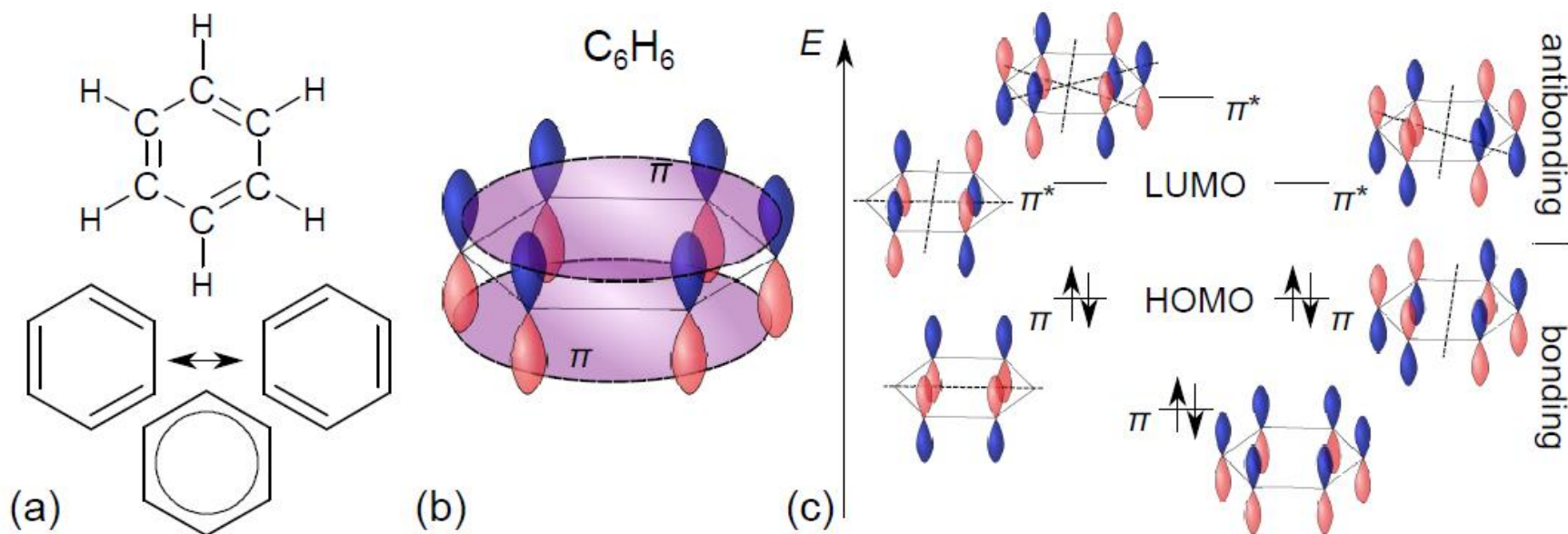
Best Research-Cell Efficiencies



Organic Solar Cells

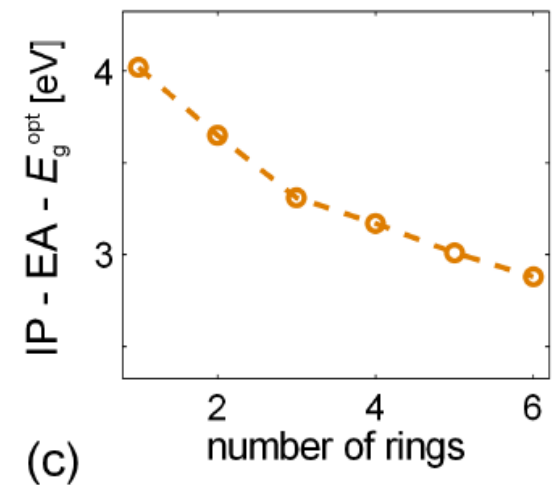
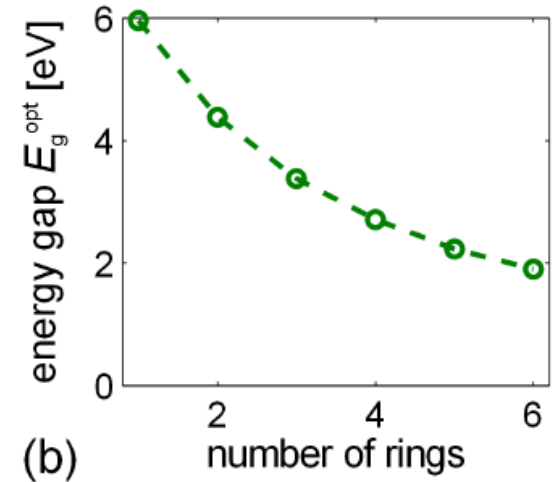
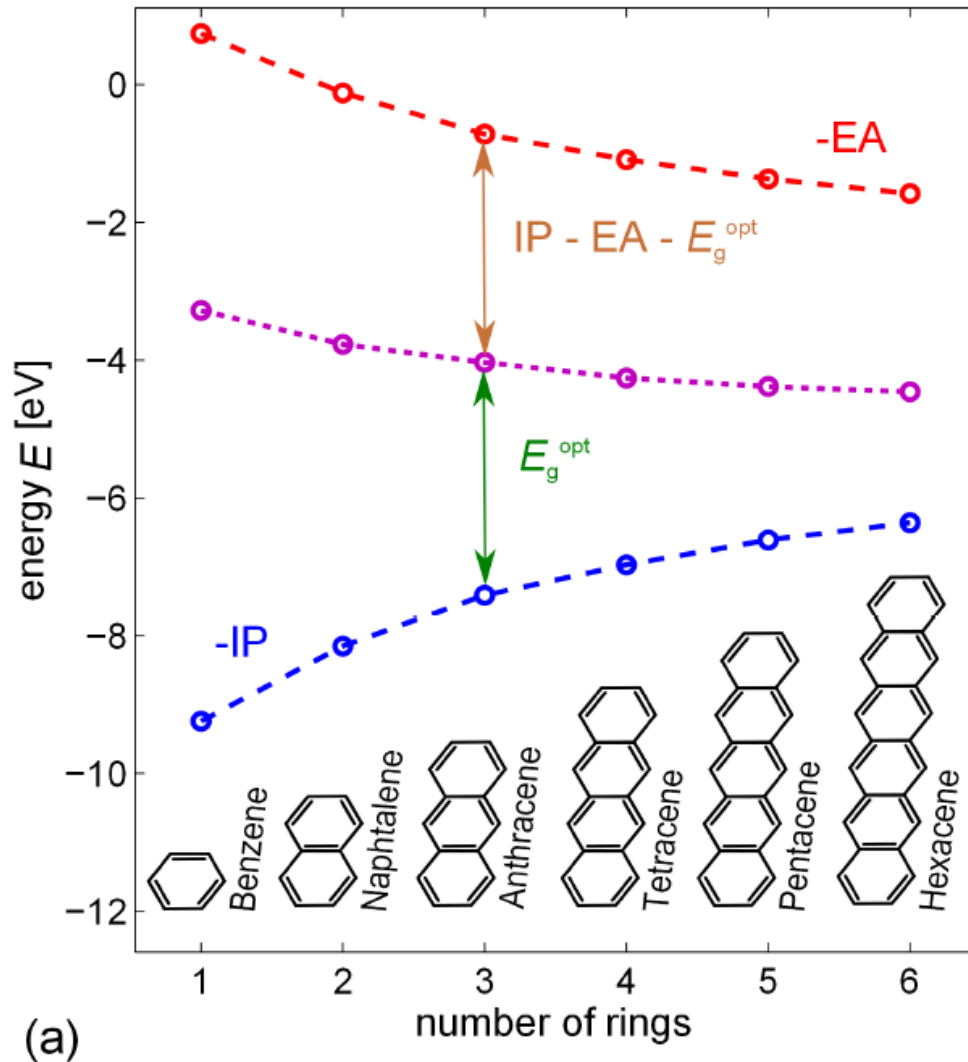


Pi-Conjugated Molecules: LCAO

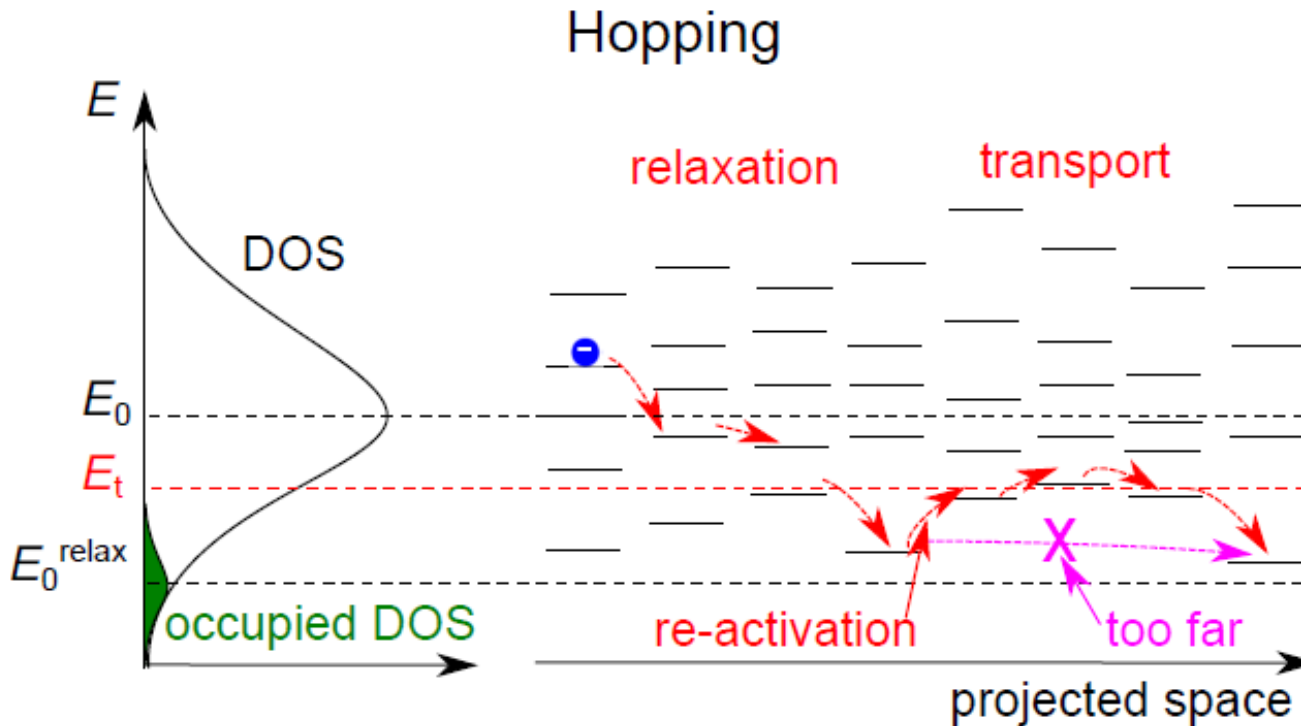


- Frontier orbitals:
 - Highest Occupied Molecular Orbital (HOMO)
 - Lowest Unoccupied Molecular Orbital (LUMO)
- HOMO LUMO transitions can be in visible range

Frontier Orbitals of Oligoacetenes

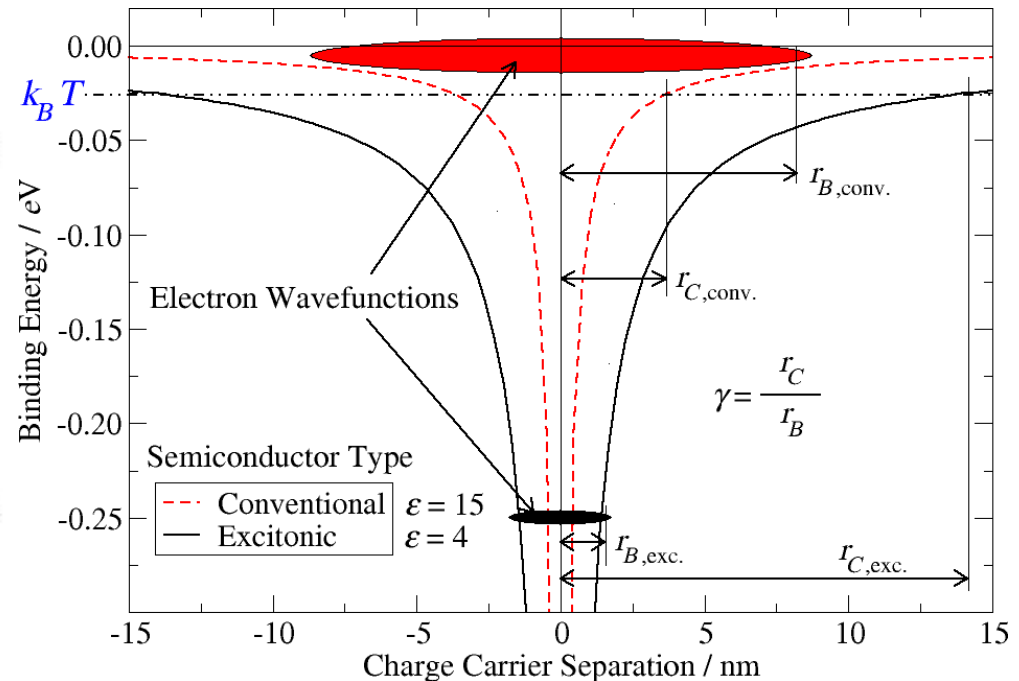
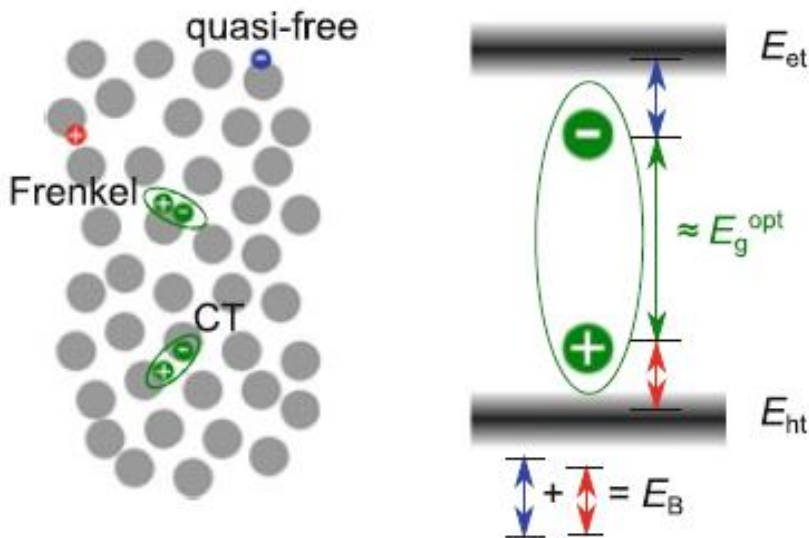


Charge Transport and Disorder



Amorphous film \rightarrow distribution of sites \rightarrow low mobility

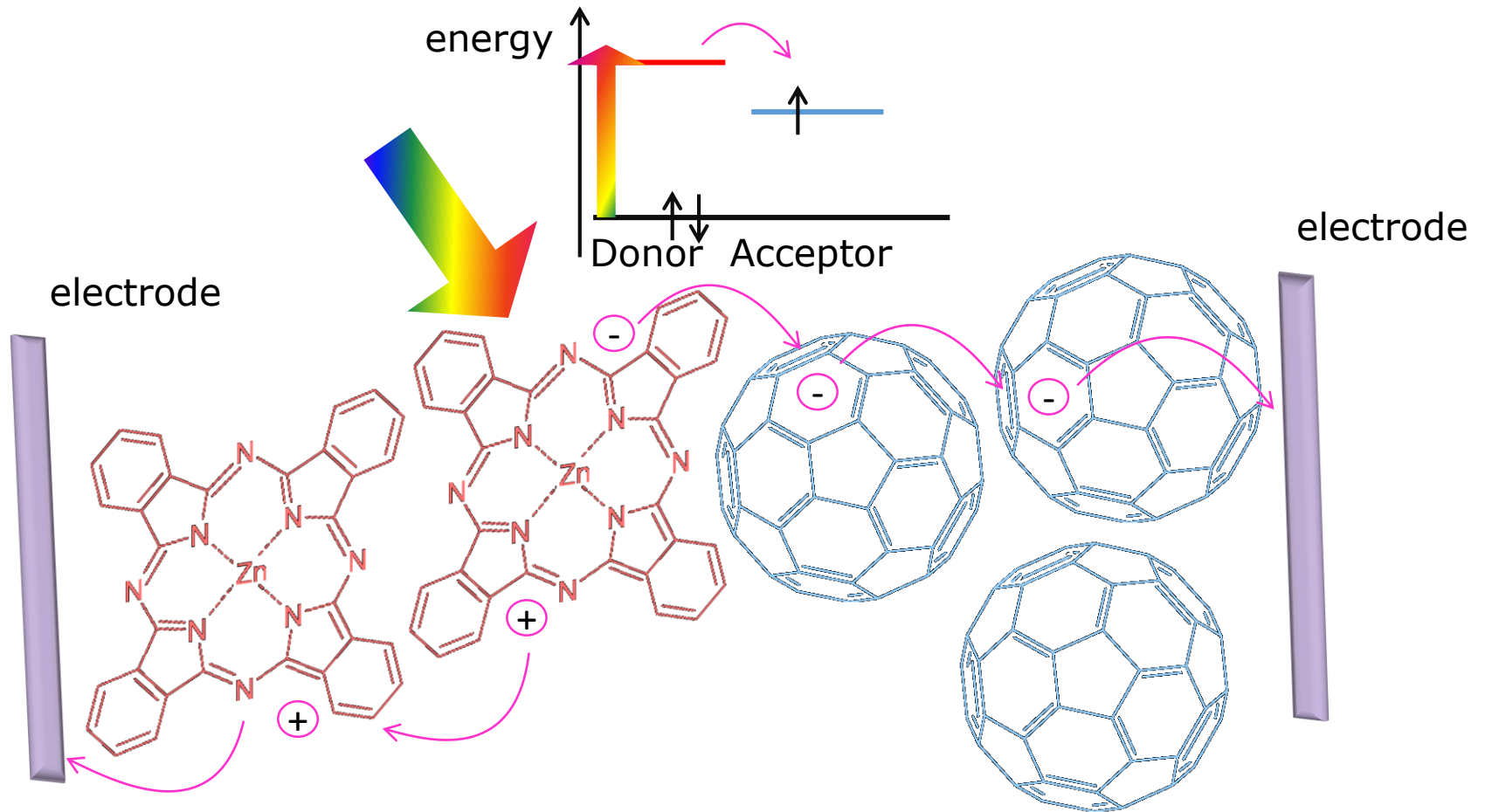
Excitonic Semiconductors



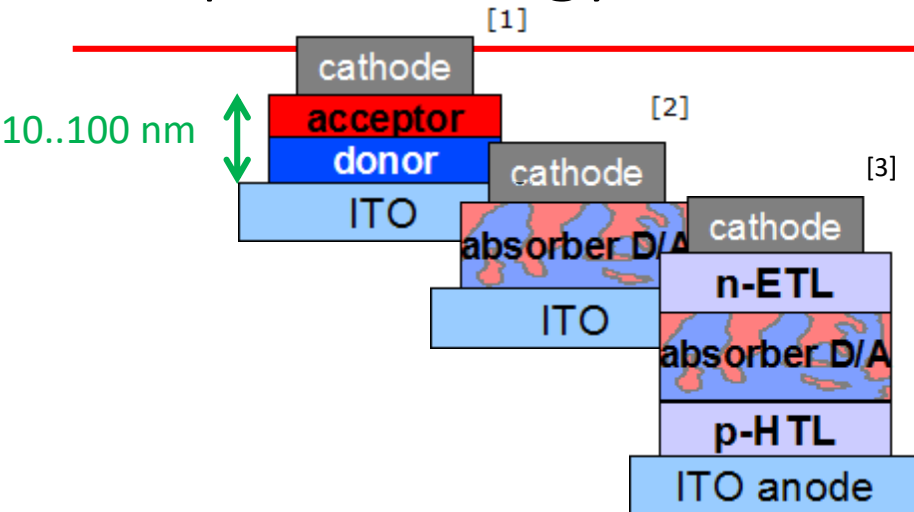
S. E. Gledhill *et al.* J. Mat Res. 20, 3167 (2005) P. Würfel, CHIMIA 61, 770 (2007)

- Molecular film: low interactions between Van-der-Waals bound molecules \rightarrow molecular properties remain
- Low dielectric constant \rightarrow high exciton binding energy

Donor-Acceptor Concept



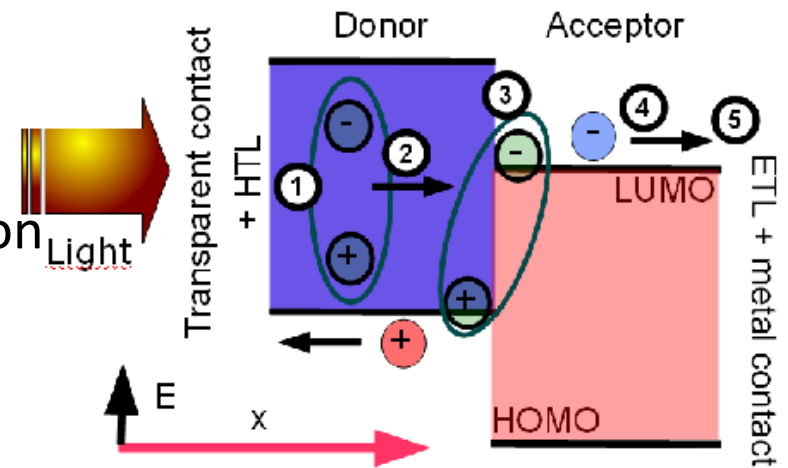
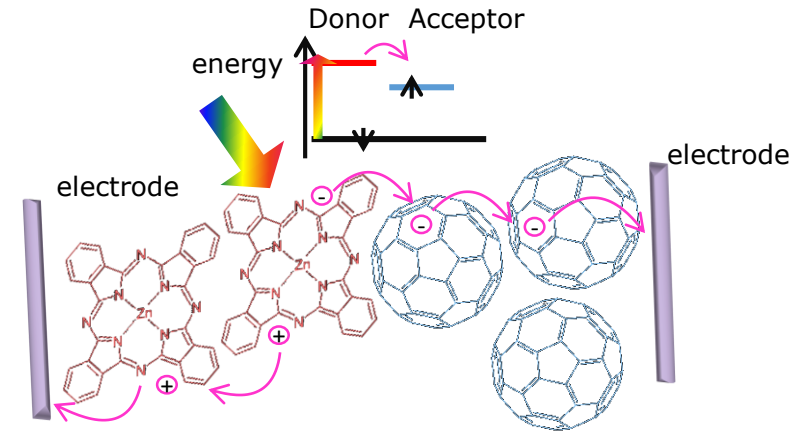
Steps of Energy Conversion



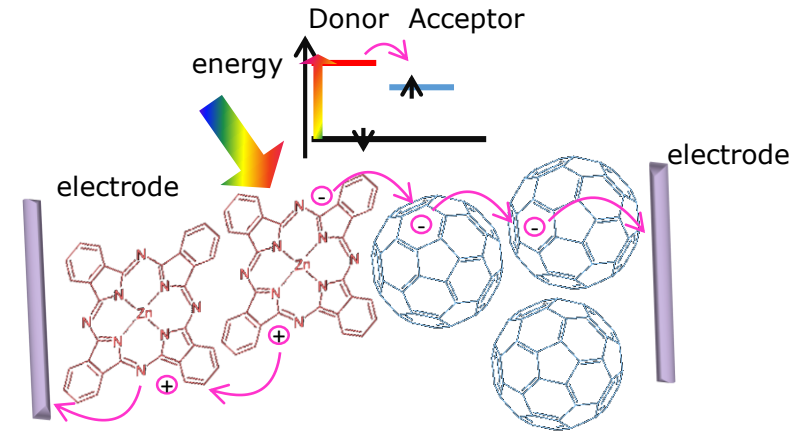
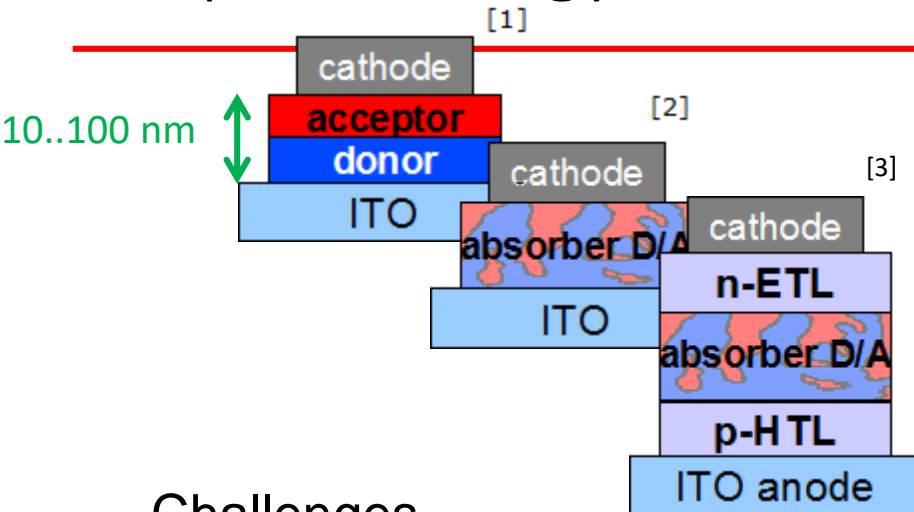
- [1] Tang, Appl. Phys. Lett. 48, 183 (1986)
- [2] Hiramoto et al. Appl. Phys. Lett. 58, 1062 (1991)
- [3] B. Maennig et al., Appl. Phys. A 79, 1 (2004)

Steps of energy conversion

- ① Exciton generation via light absorption
- ② Exciton migration (diffusion)
- ③ Exciton separation and dissociation
- ④ Charge carrier transport
- ⑤ Charge carrier collection/injection

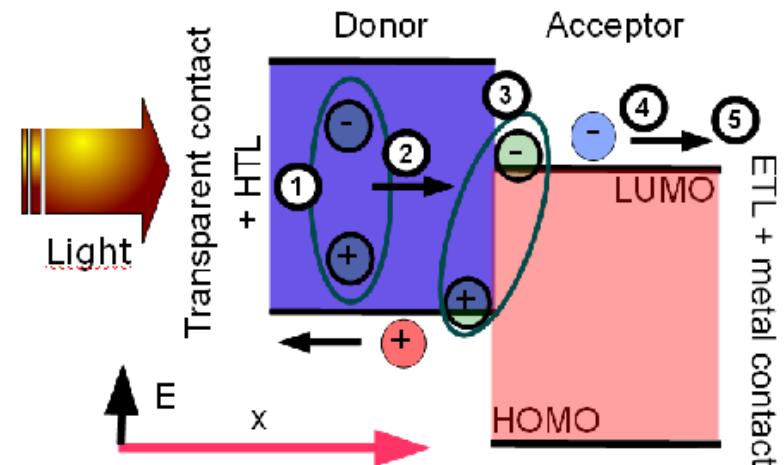


Steps of Energy Conversion



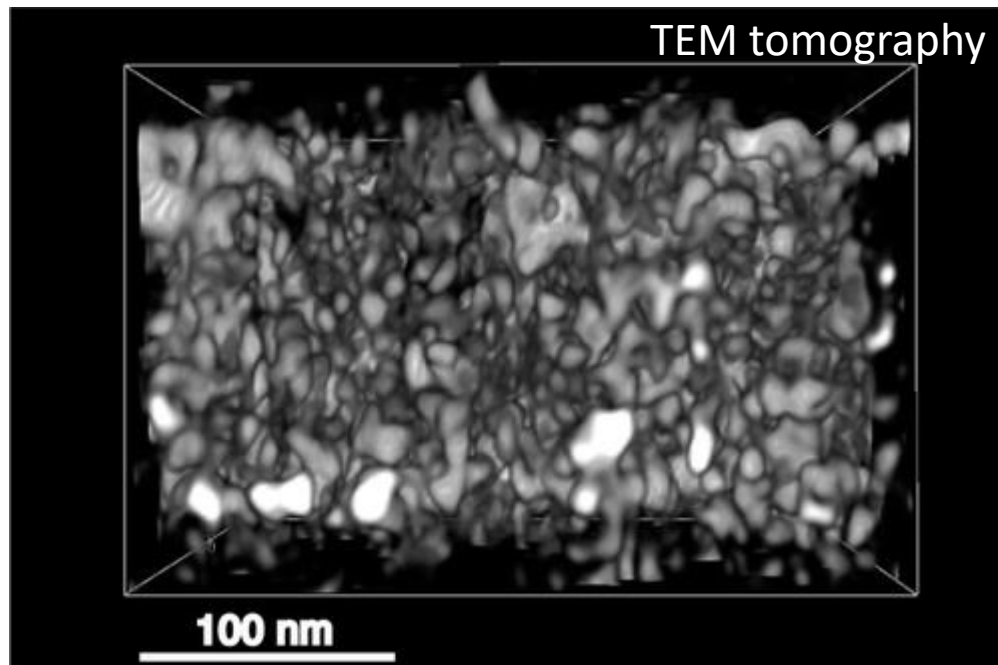
Challenges

- Disorder, poor charge transport
- Excited states hard to split
- Low fill factor
- High recombination, low voltage
- Narrow absorption, but broad onset
- Low long-term stability

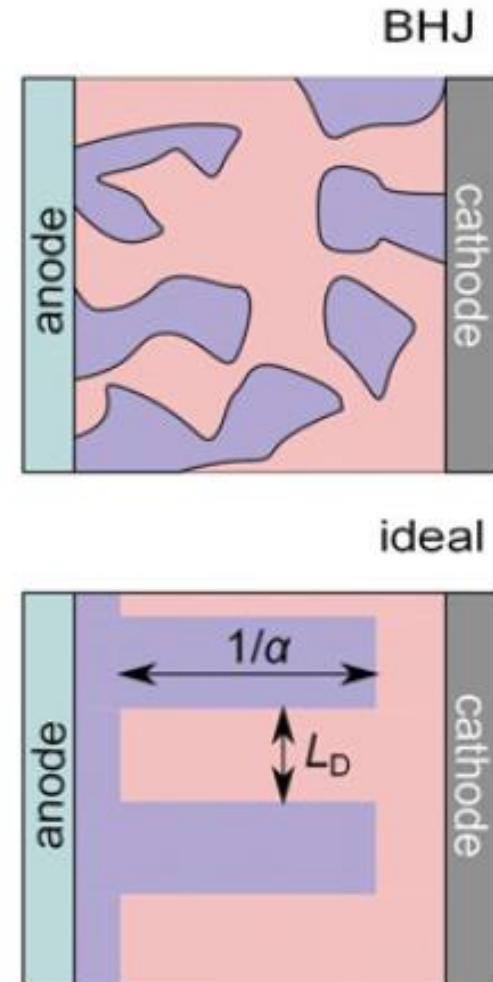


Bulk Heterojunction: Morphology

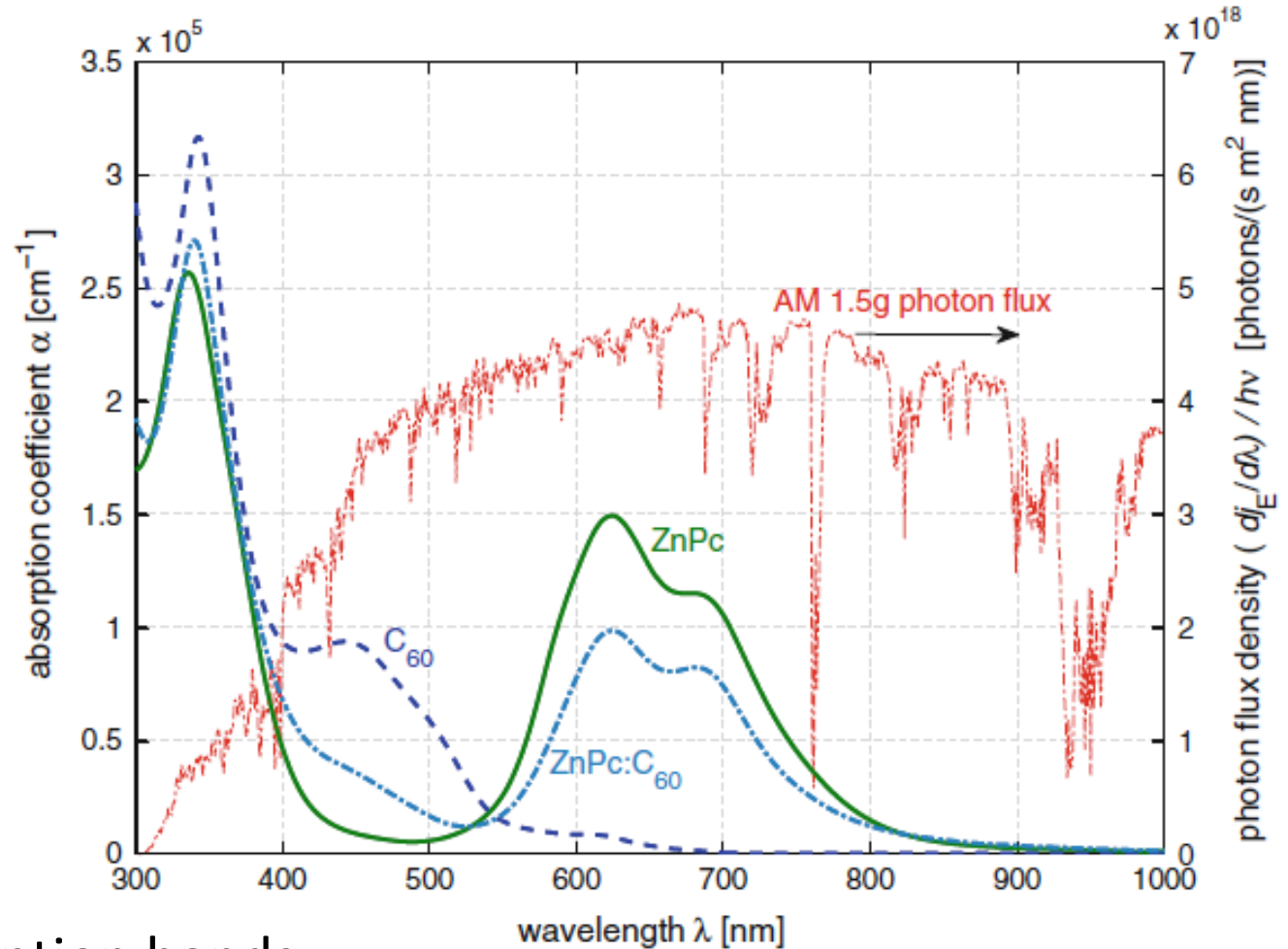
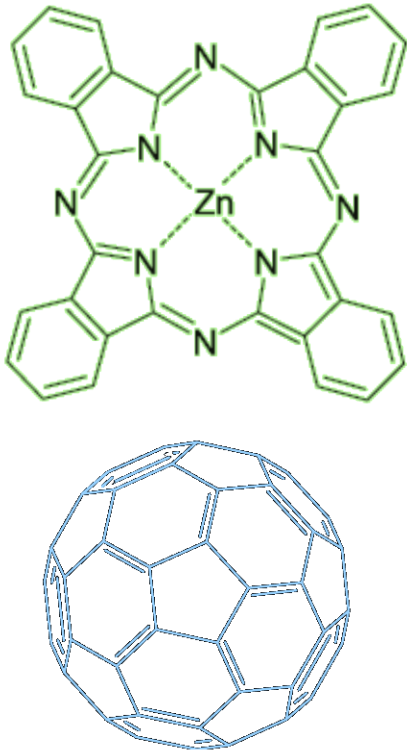
- Tune amount of mixing/demixing
 - Energy vs. entropy
 - Annealing
 - Solvents



Nano Lett., 2009, 9 (2), pp 853–855 DOI: 10.1021/nl803676e

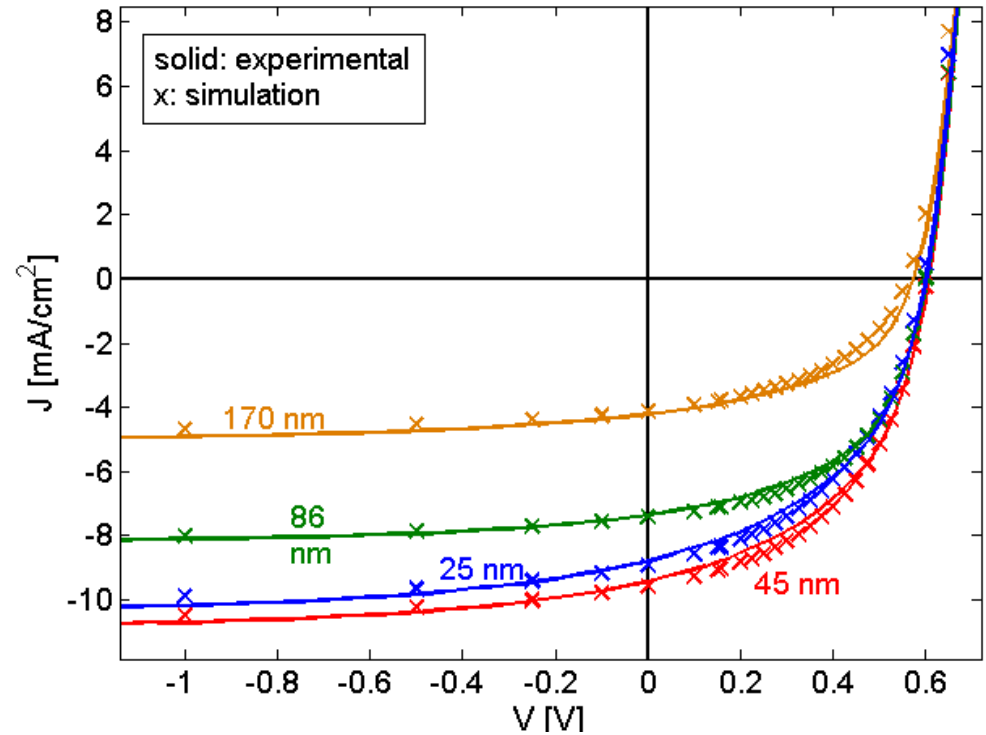
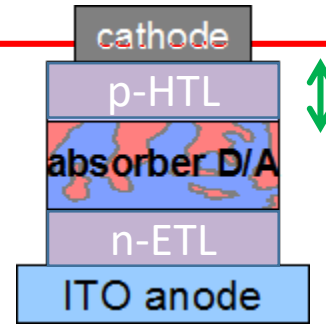
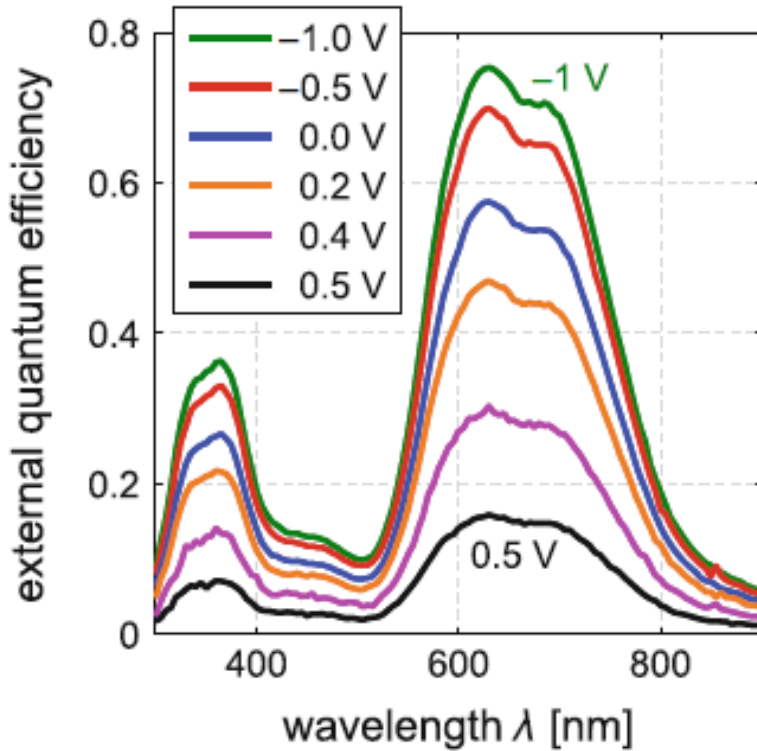


Absorption and EQE



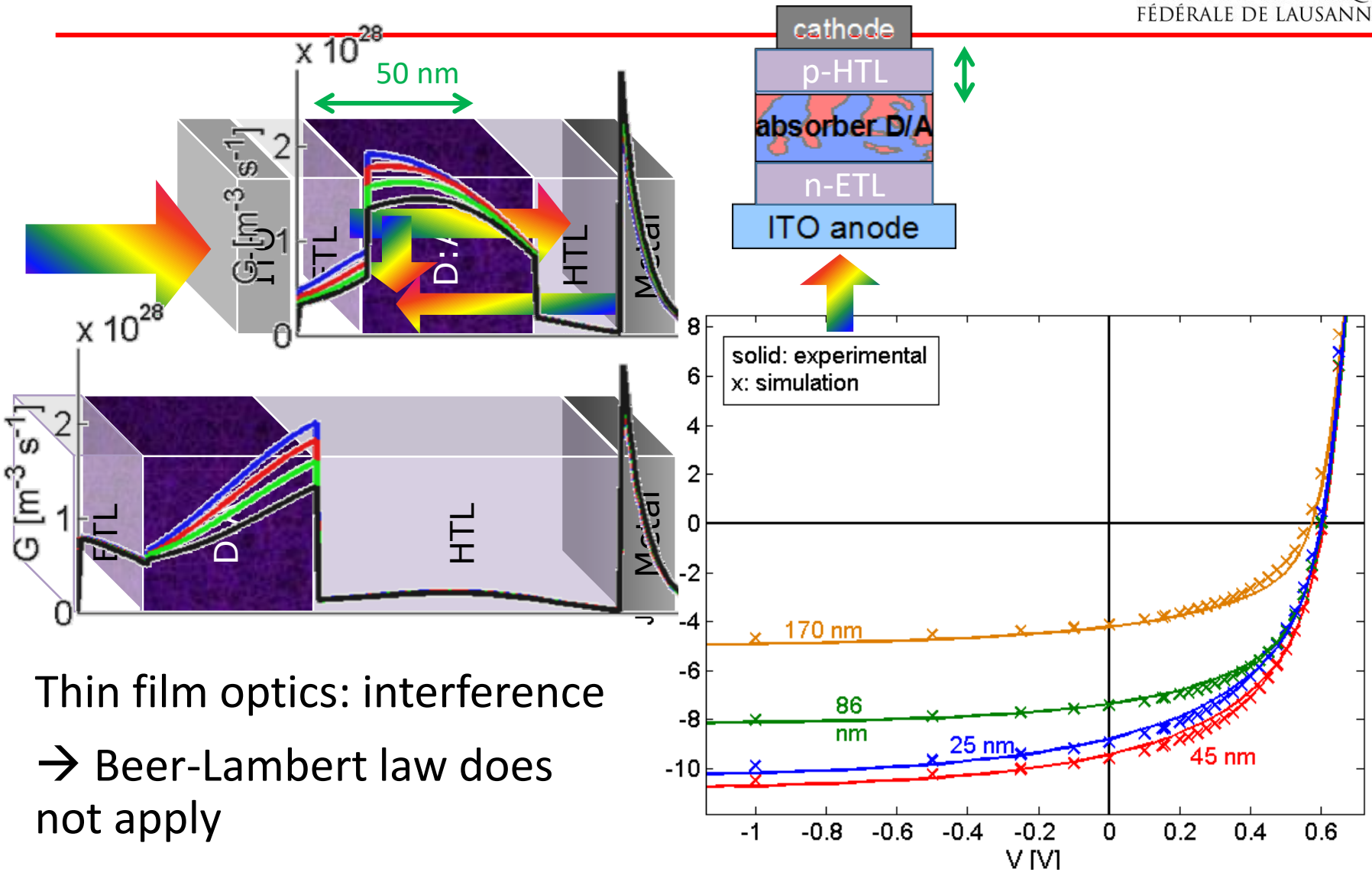
- Narrow absorption bands

EQE and JV-curve



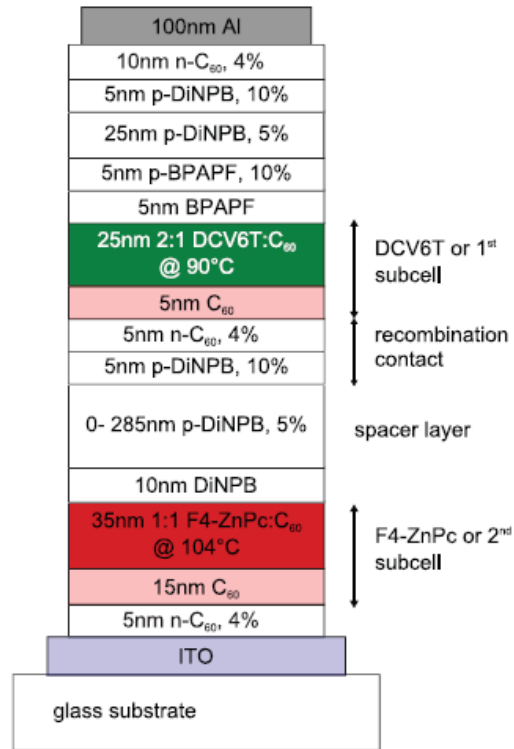
- J_{ph} depends on voltage
- Charge collection problem
- Reduces fill factor

Light Management



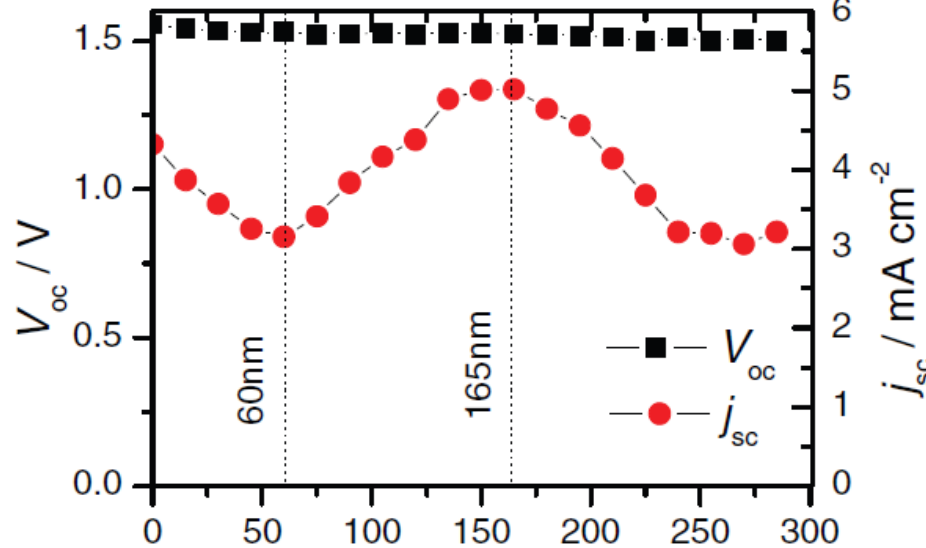
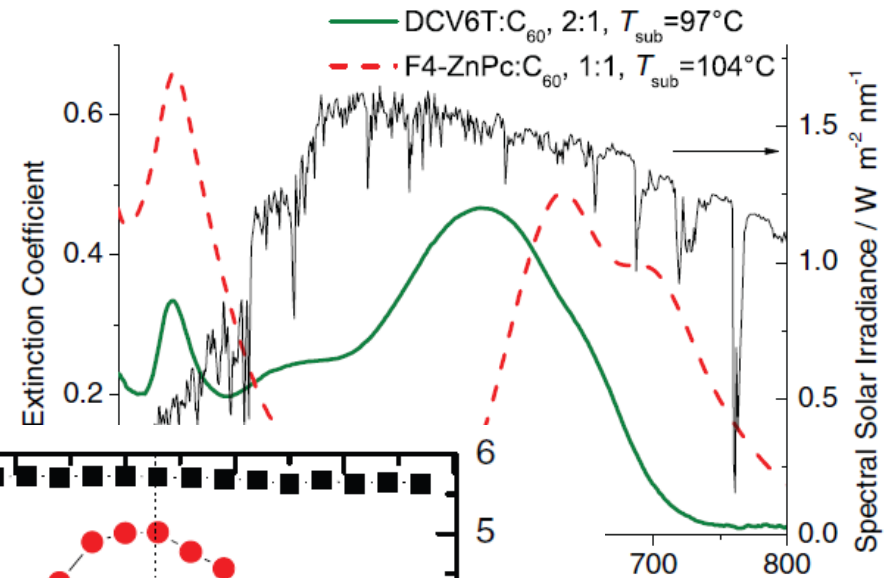
Thin film optics: interference
 → Beer-Lambert law does not apply

Tandem Solar Cells



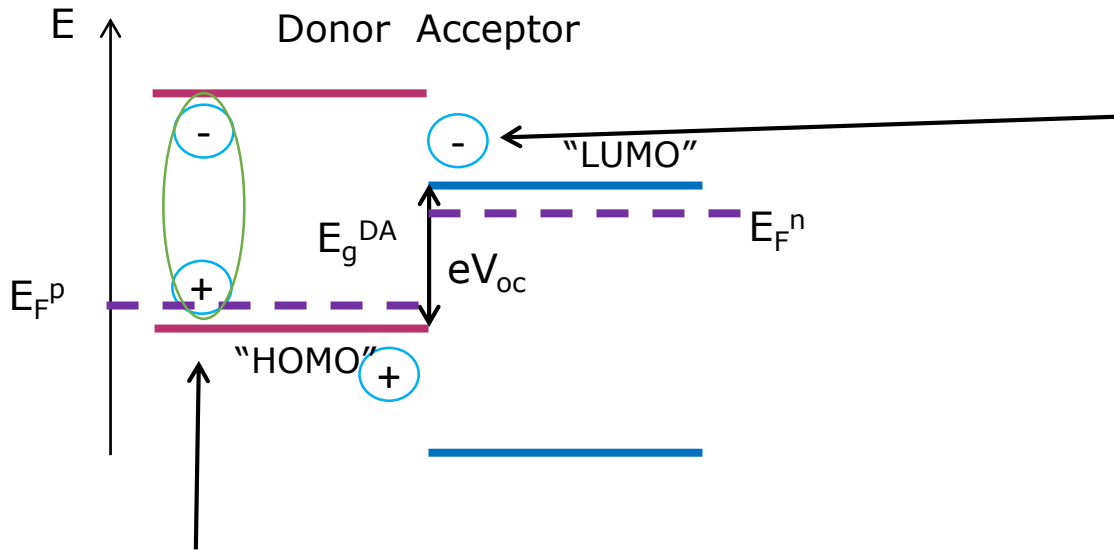
Bu

Adv. Funct. Mater. 2011, 21, 3019–3028



- Current matching

How to Increase Current and Voltage

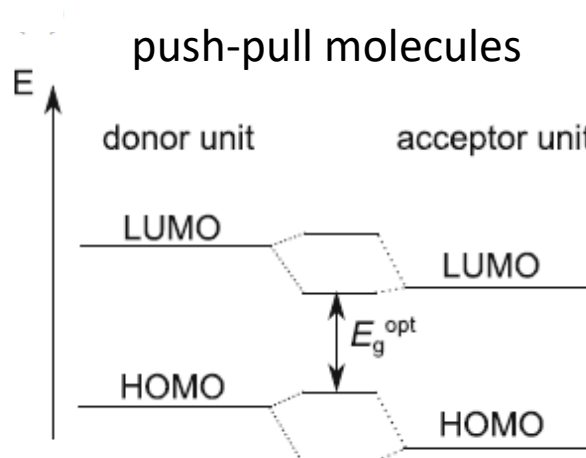


Voltage:

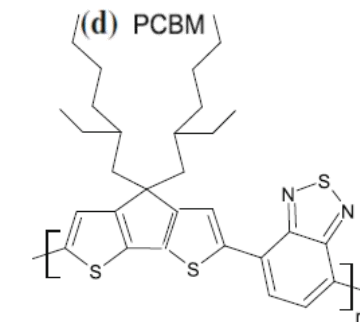
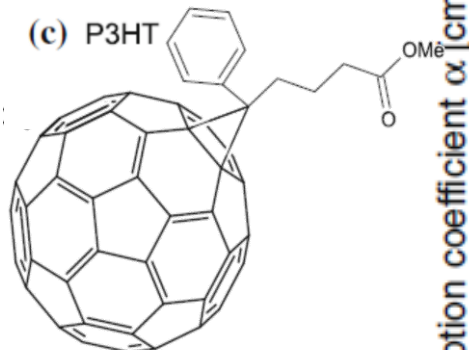
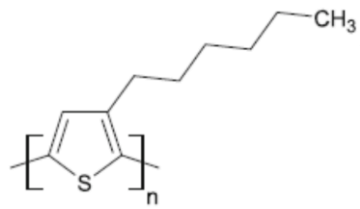
- Reduce "offset" energies
- Combination of donor and acceptor

Current:

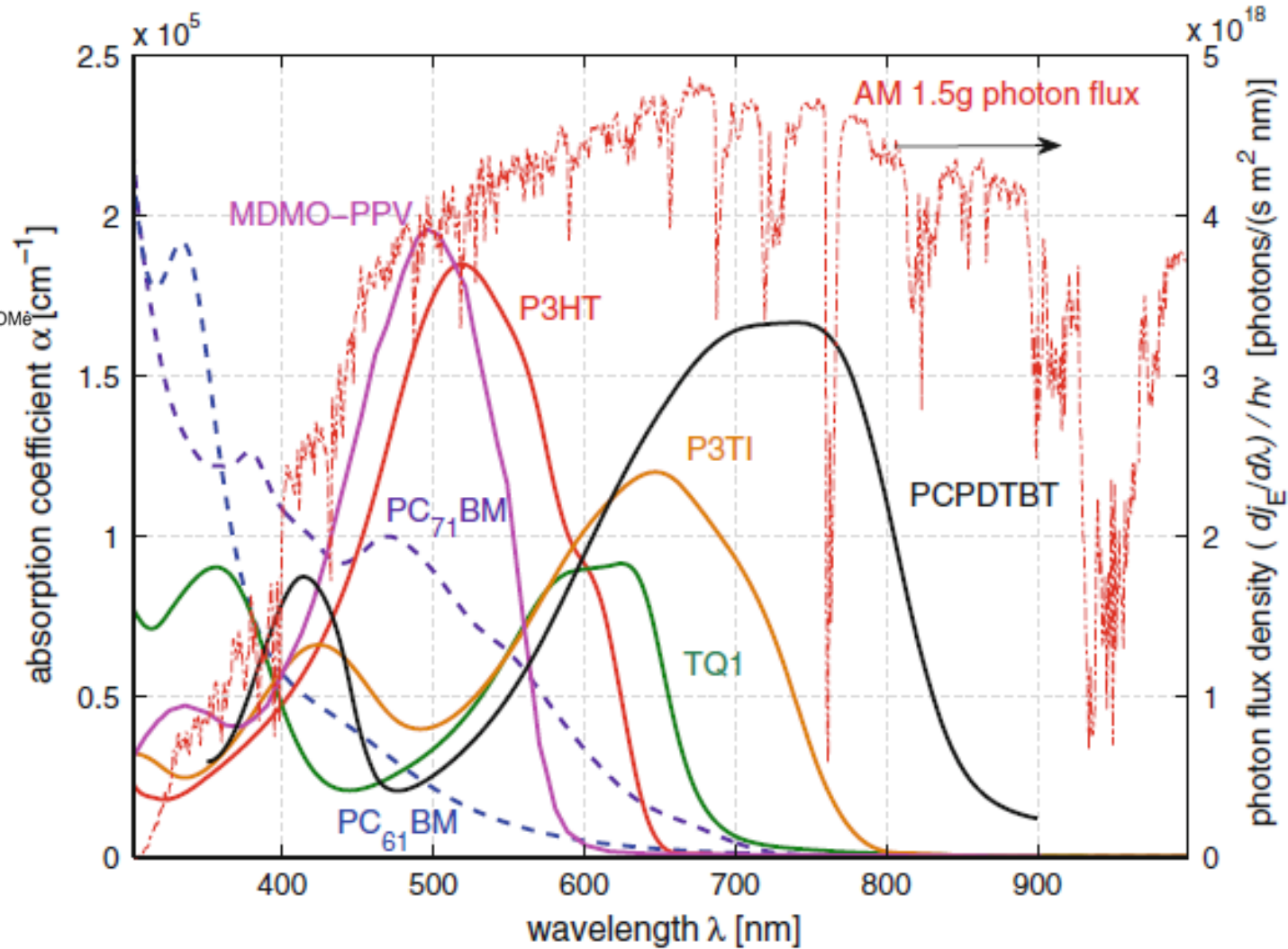
- Low band gap materials
- Complementary absorption of donor and acceptor



Tuning Absorption in Polymers

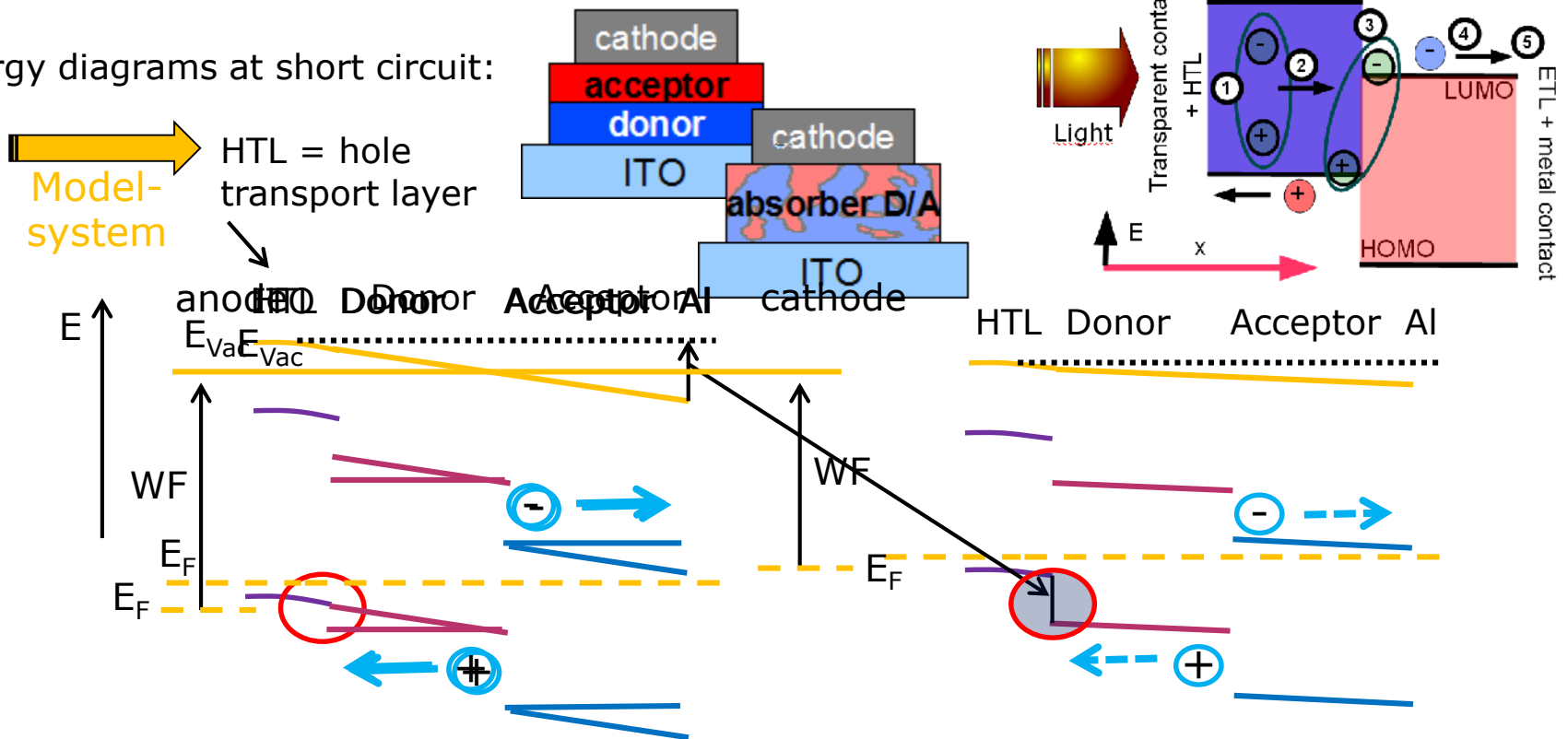


(e) PCPDTBT



Working Principle and Role of Contacts

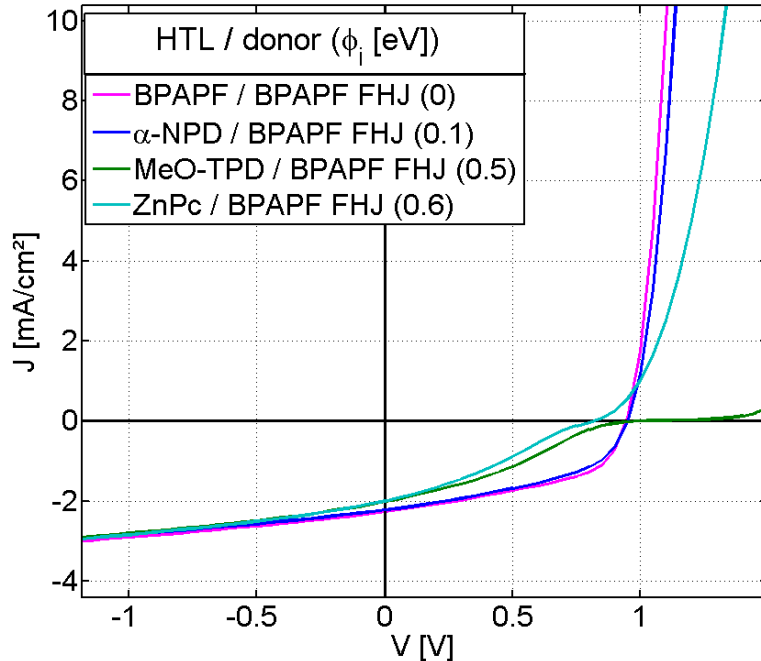
Energy diagrams at short circuit:



→ Provide built-in field due to difference in work functions

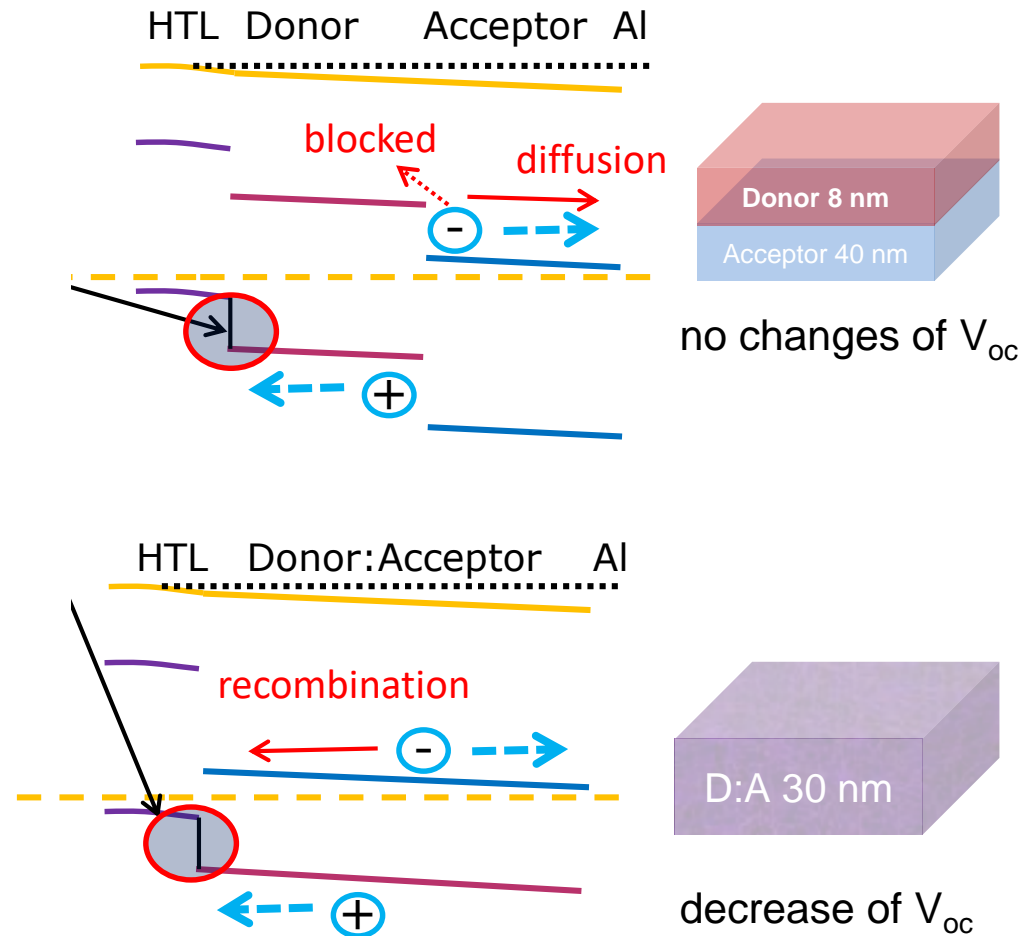
Flat vs. Bulk Heterojunction

Energy diagrams at short circuit:

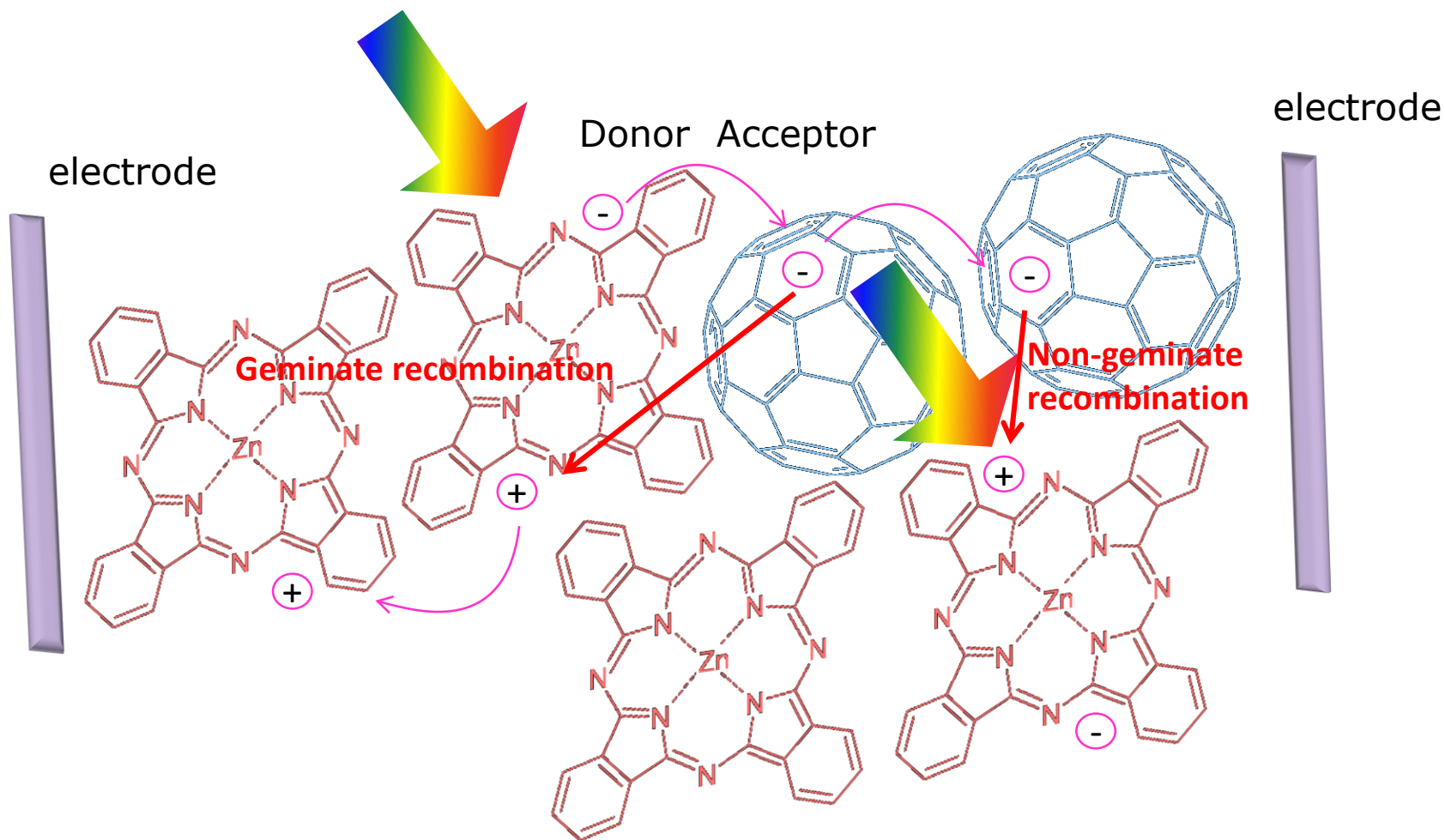


Missaligned contacts \rightarrow S-Shape

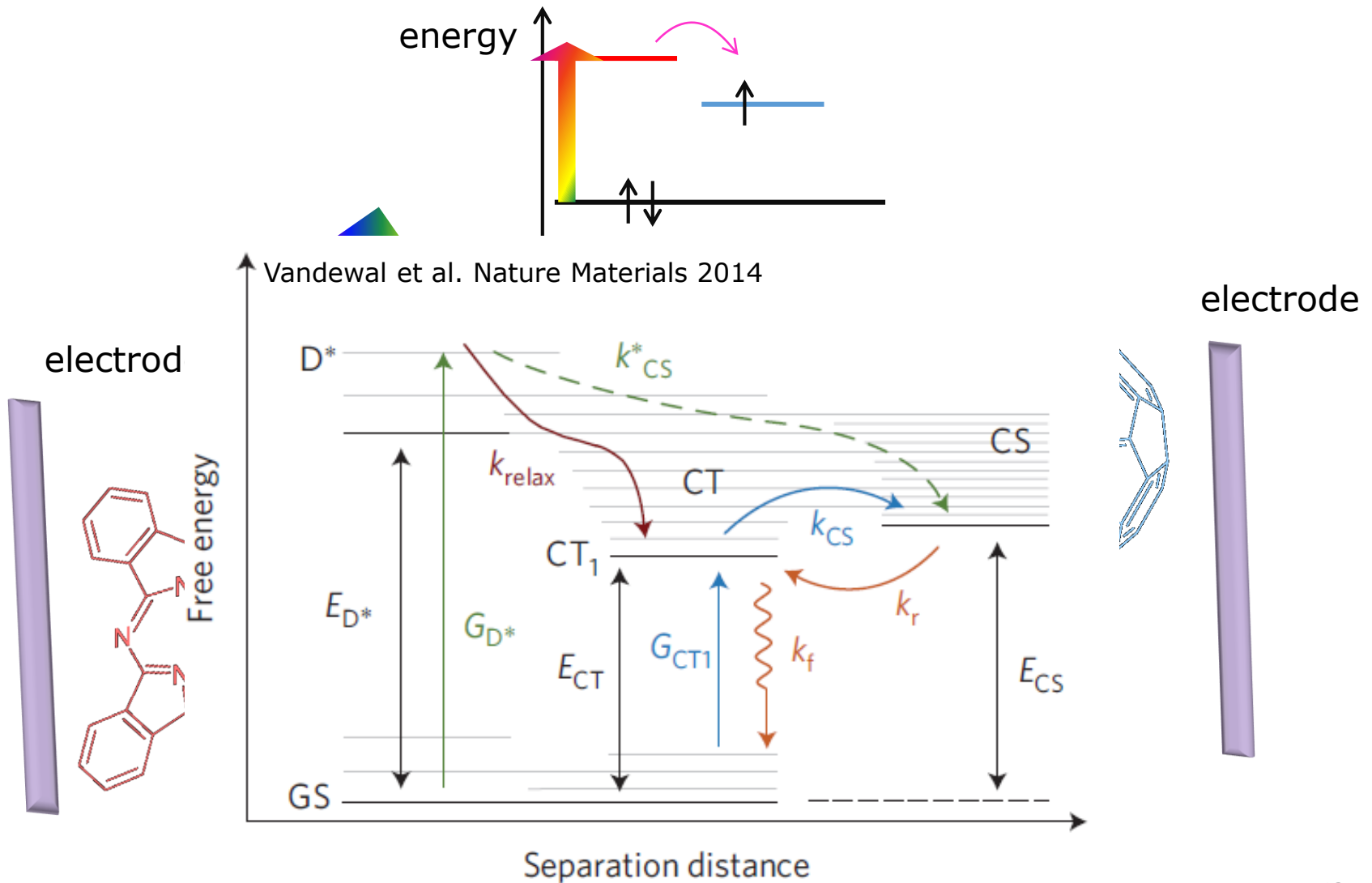
\rightarrow Build selective device!



Geminate Recombination

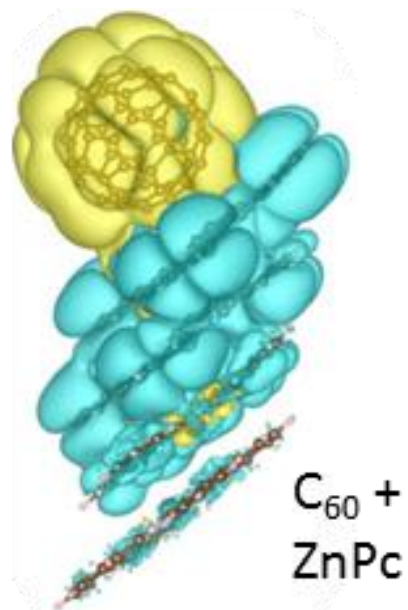


Charge Transfer States: hot, (de)localized?



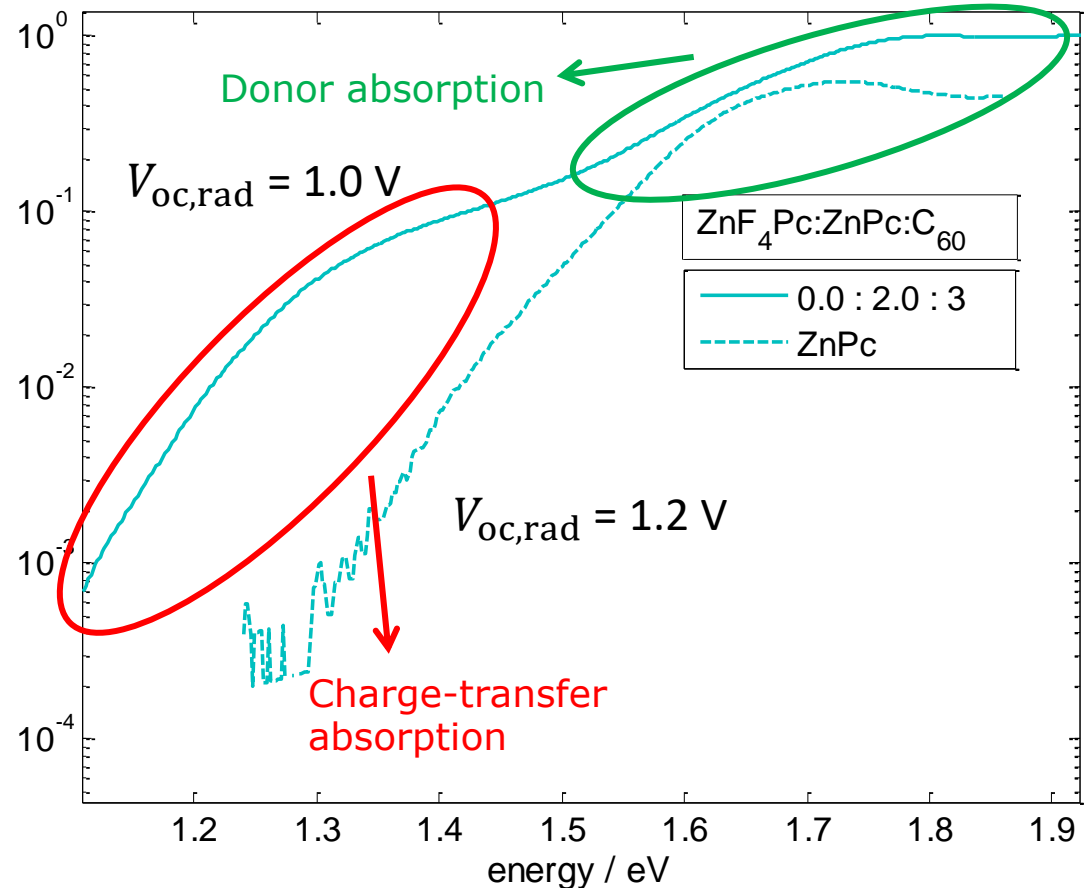
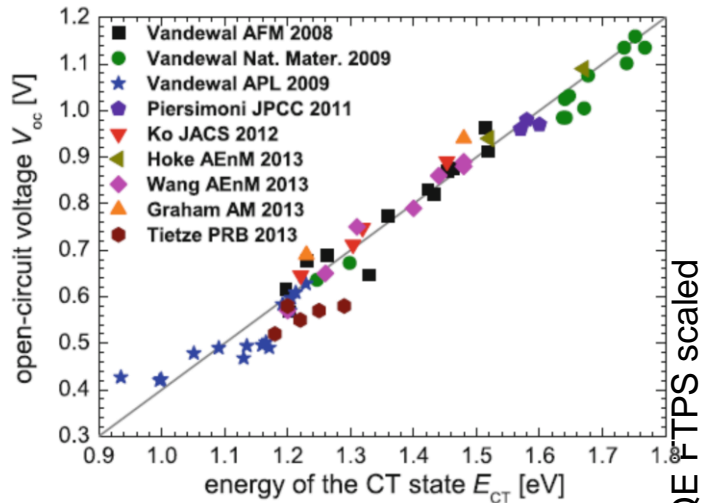
Charge Transfer State: Delocalized?

Compare to **TD DFT simulations**



In collaboration with U. Roethlisberger, EPFL

Charge Transfer State and V_{oc}

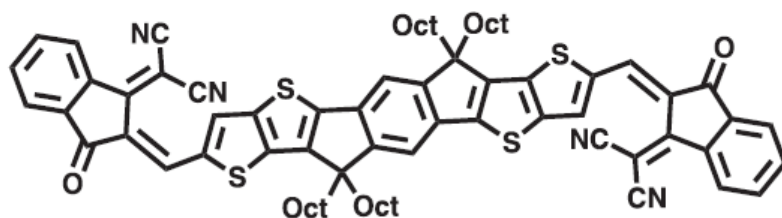


$$V_{oc,rad} = \frac{k_B T}{e} \ln \left(\frac{J_{ph}}{J_{em,0}} + 1 \right)$$

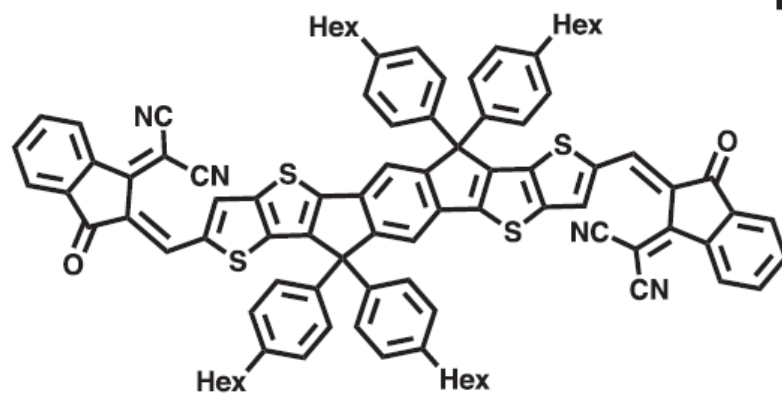
$$J_{ph} = e \int EQE(E) \Phi_{AM1,5g}(E) dE$$

$$J_{em,0} = e \int EQE(E) \phi_{BB}(T_0) dE$$

small-molecule acceptors



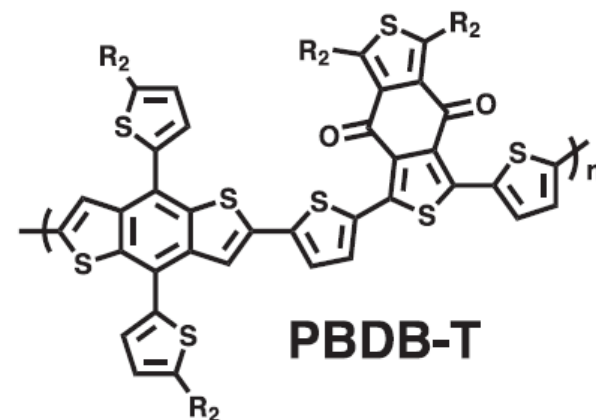
C8-ITIC



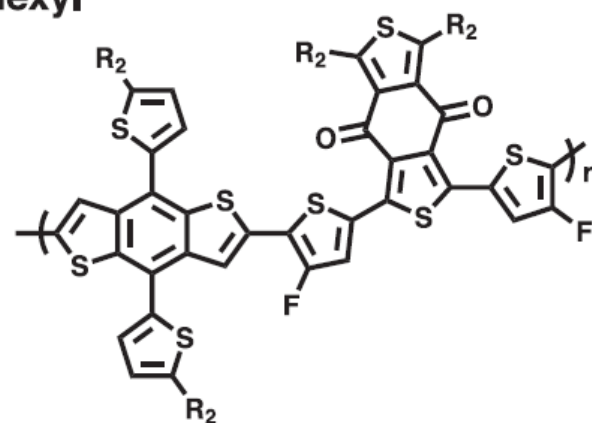
ITIC

$R_1 = \text{octyl}$
 $R_2 = \text{2-ethylhexyl}$

donor polymers



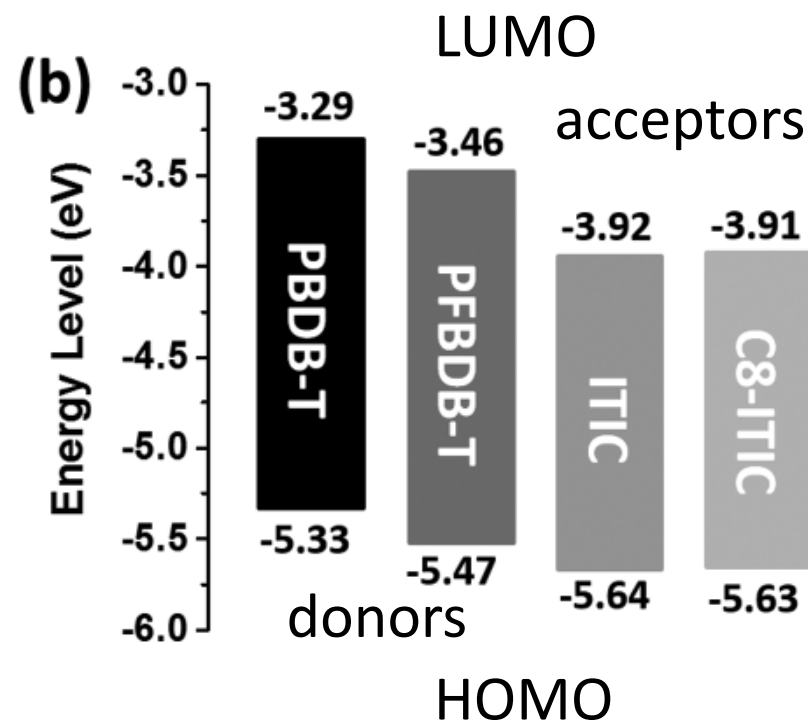
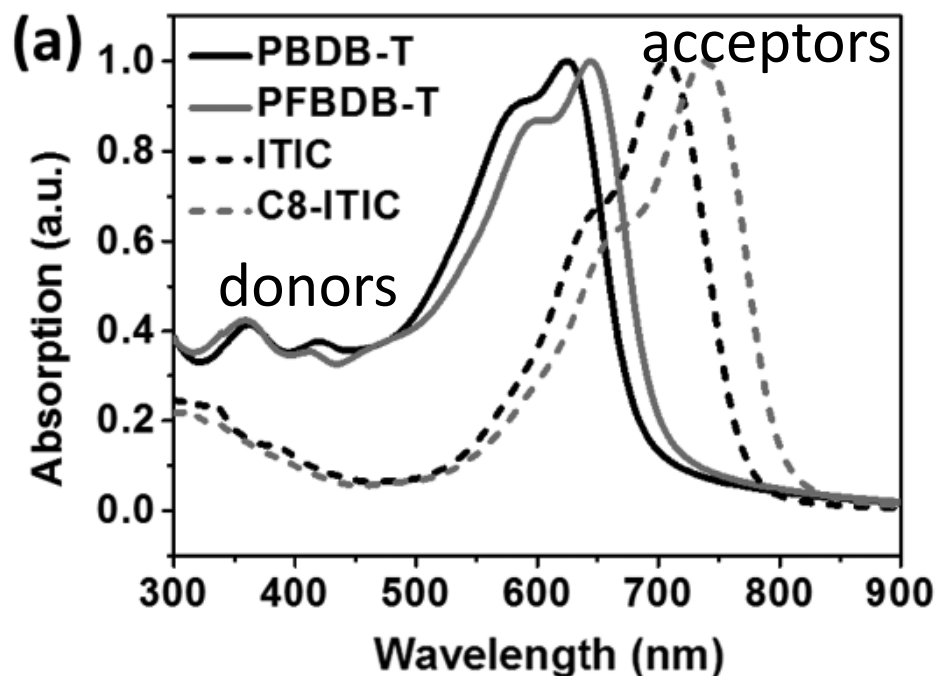
PBDB-T



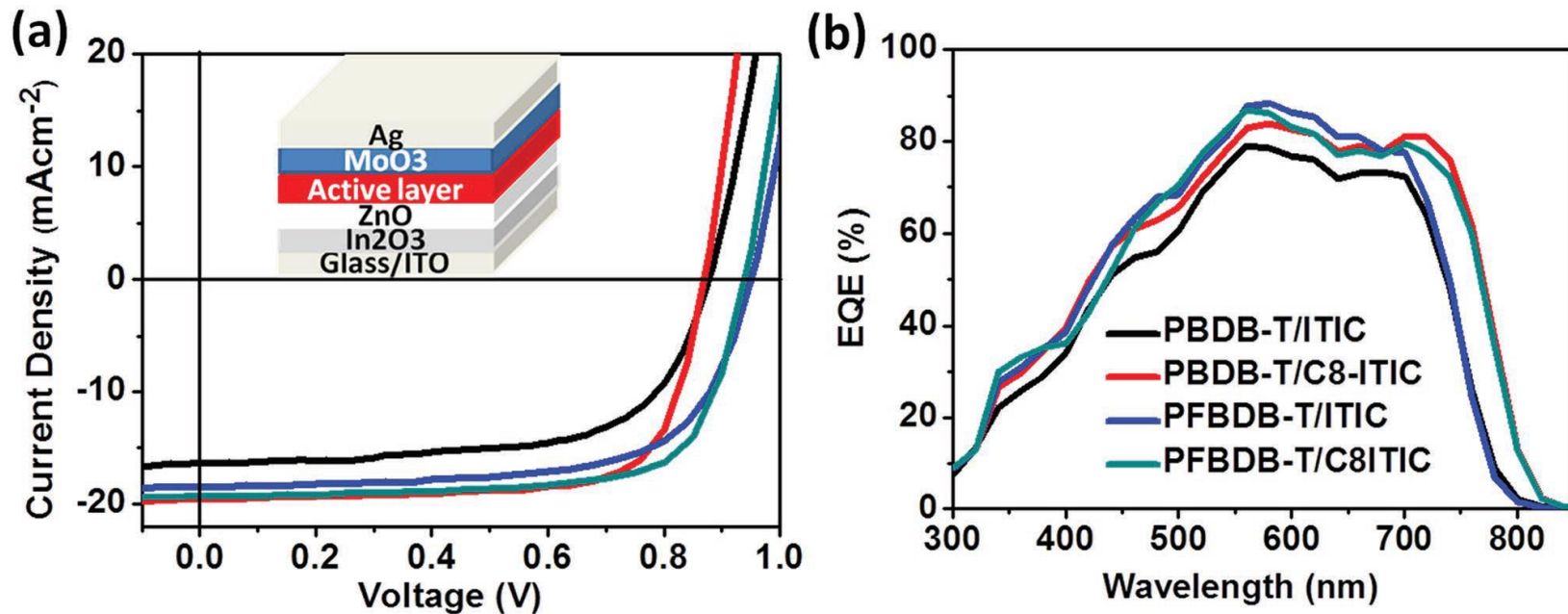
PFBDB-T

State-of-the-Art Materials and Efficiencies

Adv. Mater. 2018, 30, 1705209



State-of-the-Art Efficiencies

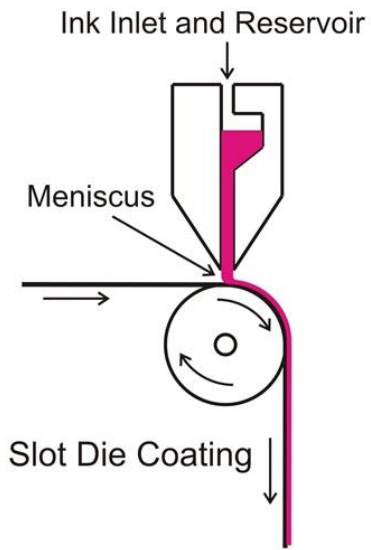


power-conversion efficiency > 13 %

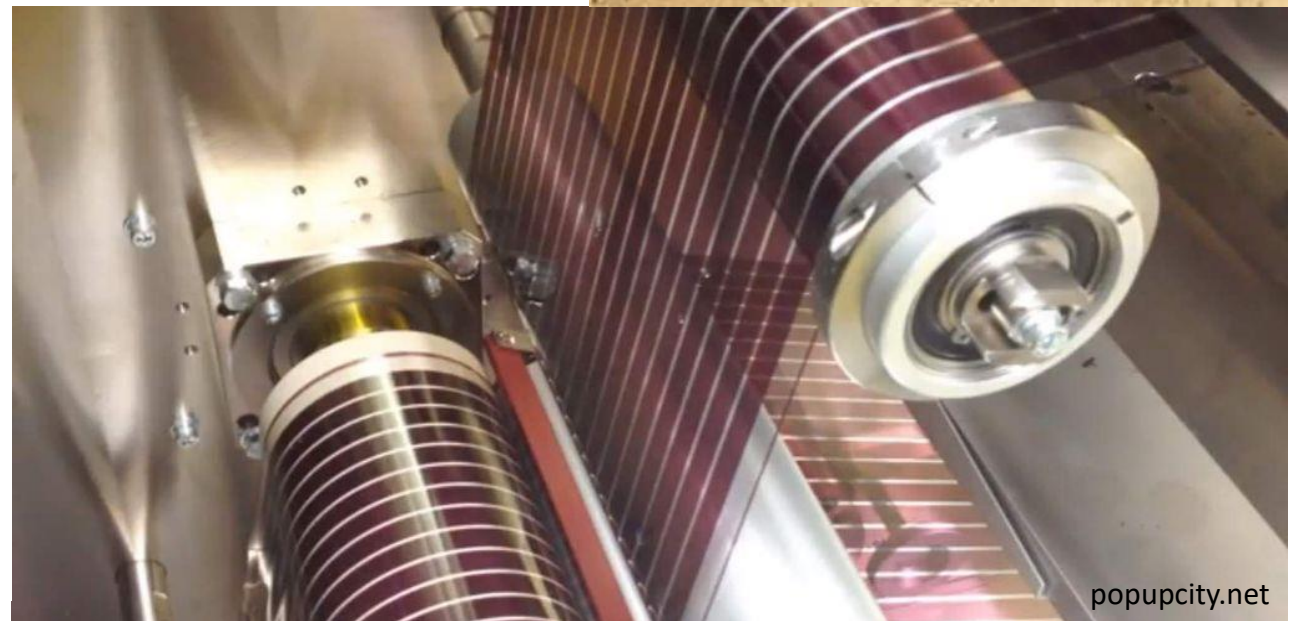
See also: *J. Am. Chem. Soc.*, 2017, 139 (21), pp 7148–7151

Fabrication

- Low-Cost: Roll-to-roll
 - Printing
 - Slot die coating
 - Evaporation



<https://www.tu-ilmenau.de/>



Organic Photovoltaics State of the Art

- ✓ Building integrated, Flexible, Colorful, **Semitransparent**
- ✓ Record 13.2 %
- Stability
 - In module/film 7%
 - Not really in market yet
 - Low efficiency



Future applications



Summary: Organic semiconductors

... have a huge potential

- low cost roll to roll and solution processability
- large area and ultra-thin devices
- variety of different hydrocarbons

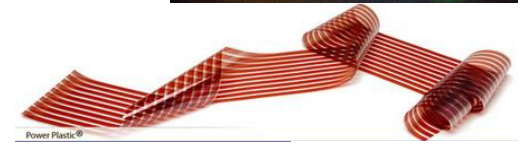


... are well suited for solar cells

- low energy input
- different dyes
- abundant



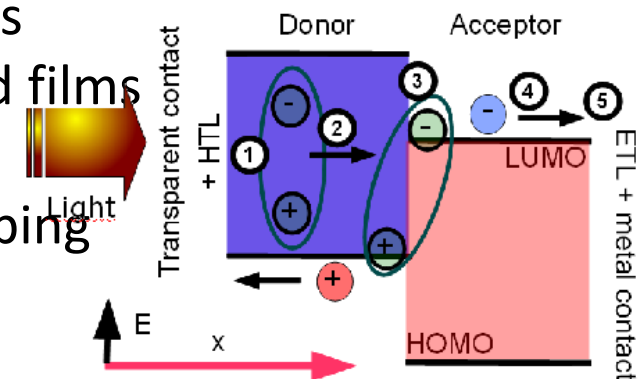
heliatek.com



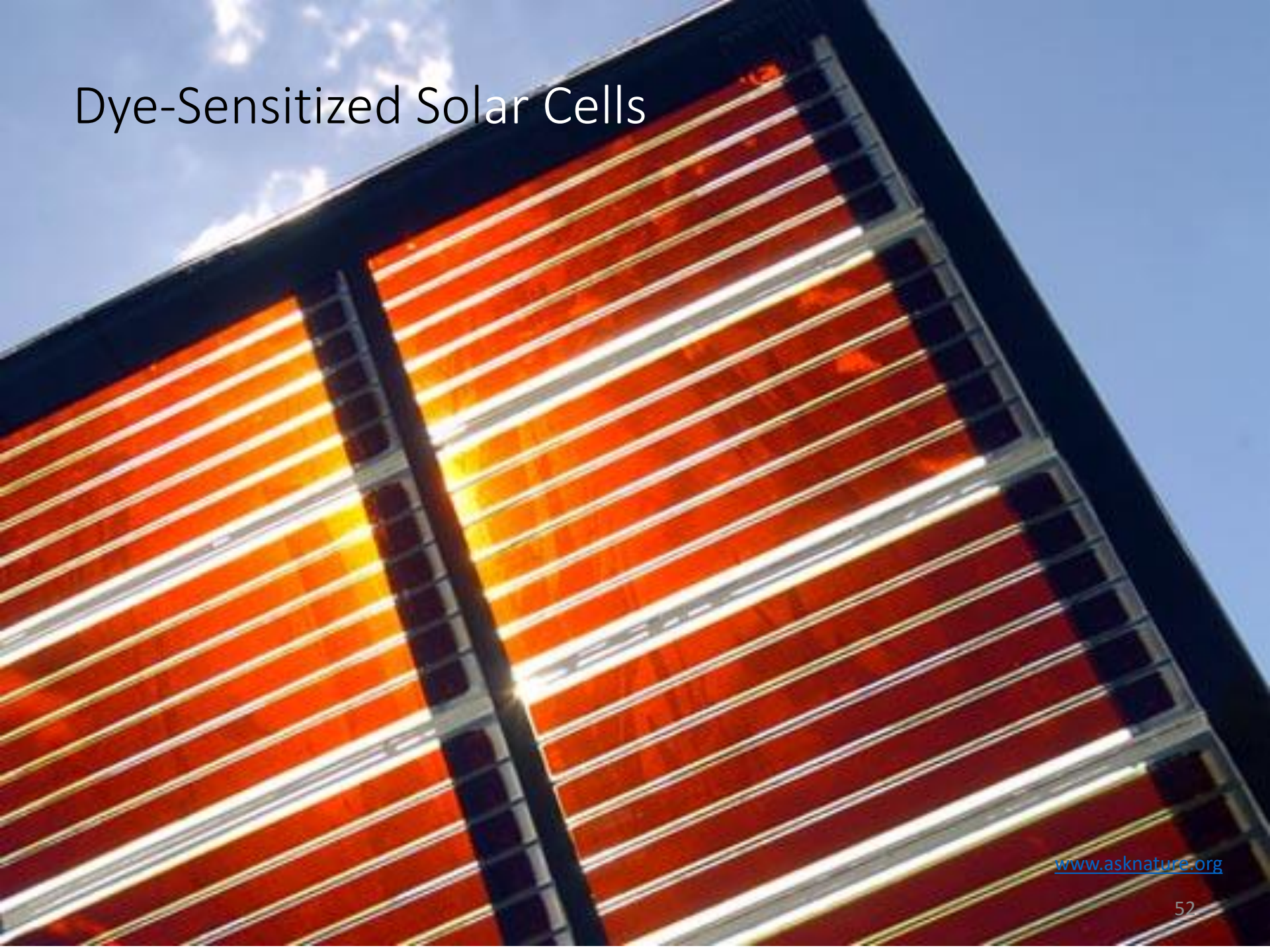
konarka.com

... are different

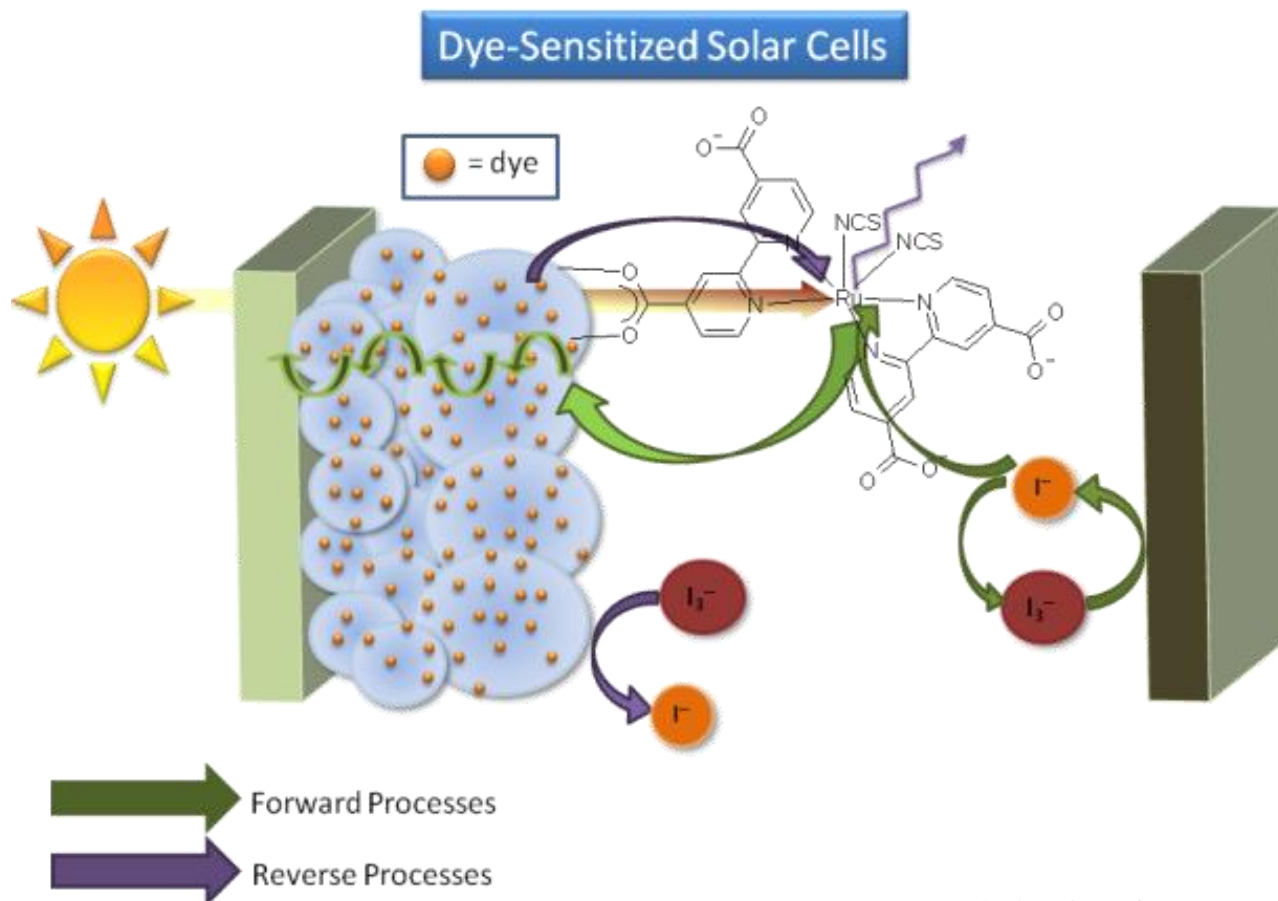
- film consists of weakly bound molecules
- mostly amorphous and even intermixed films
- optical excitation is localized
- charge transport occurs mainly via hopping
- optical and electrical gap decoupled



Dye-Sensitized Solar Cells



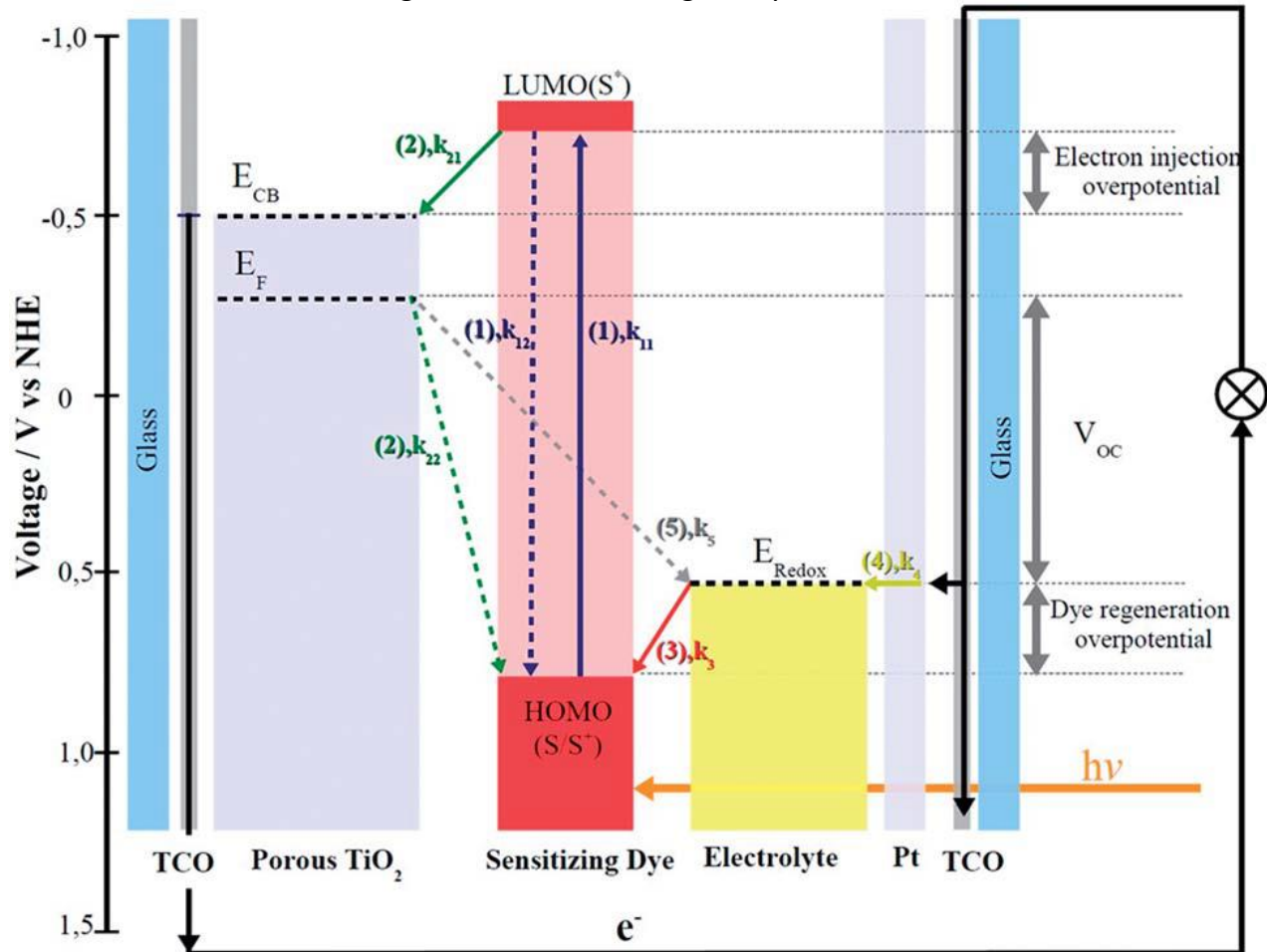
Dye-Sensitized Solar Cell: Schematics



- Absorption on monolayer of dye, decoupled from transport
- Nanostructure → surface area

Dye-Sensitized Solar Cell: Energetics

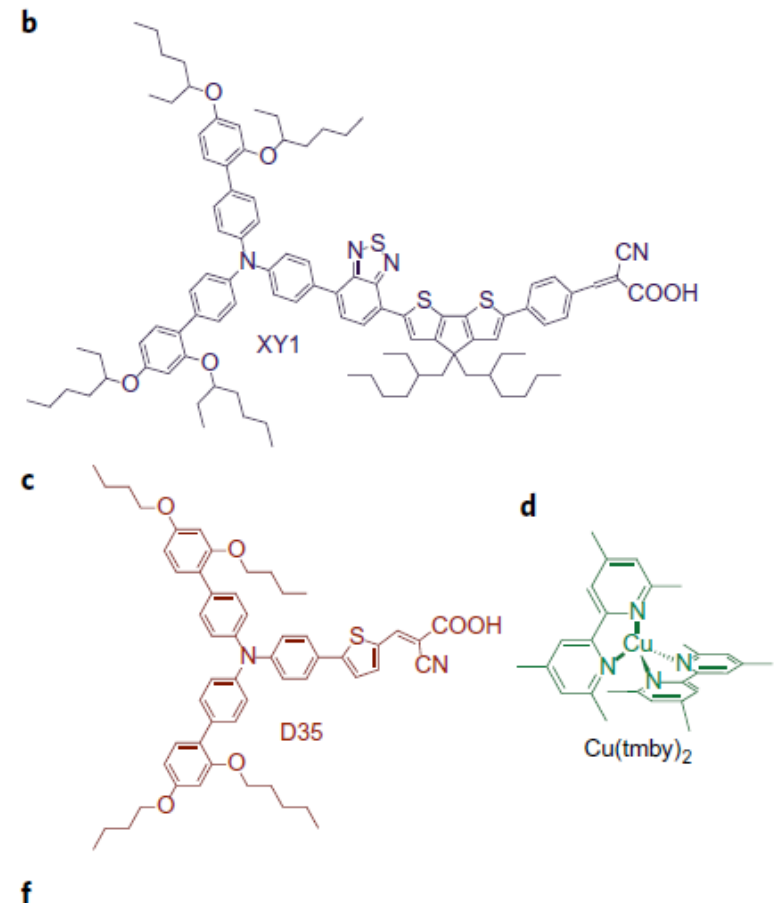
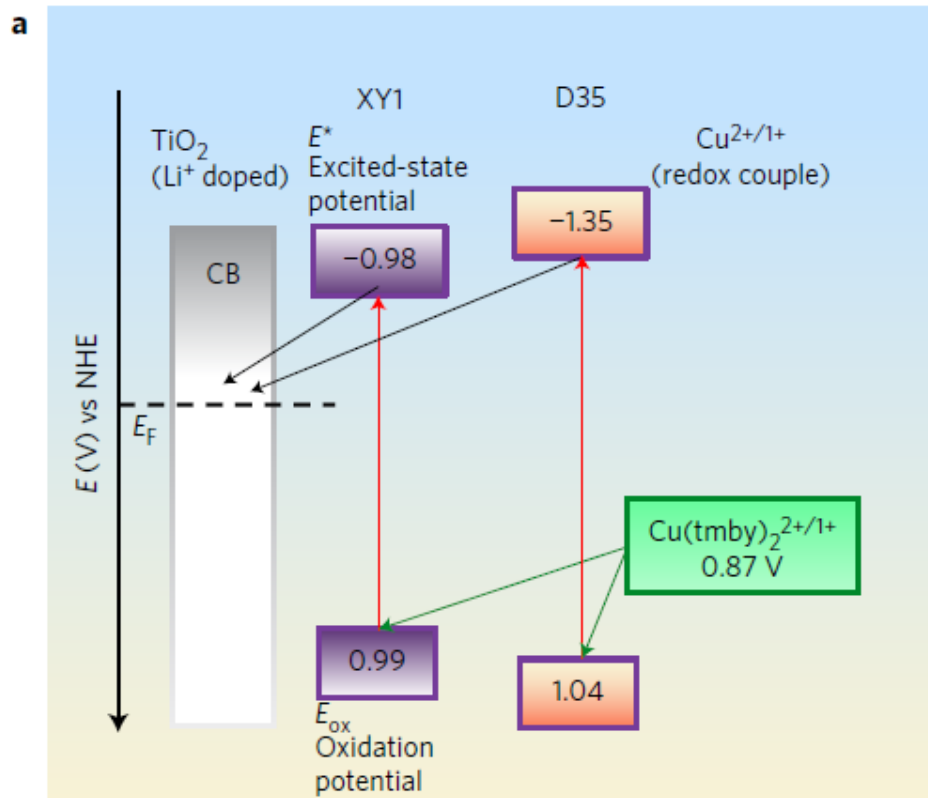
Maçaira, J., Andrade, L. & Mendes, A. Modeling, simulation and design of dye sensitized solar cells. *RSC Adv.* **4**, 2830–2844 (2013).



- Redox potential of electrolyte fixed

Dye-Sensitized SC: Recent Developments

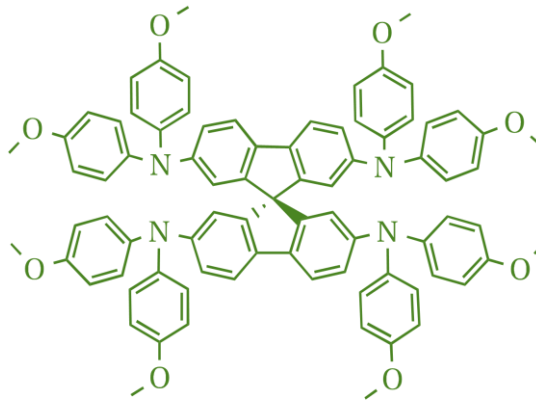
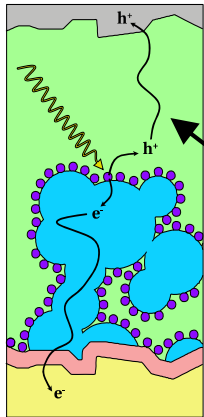
Freitag, M. *et al.* Dye-sensitized solar cells for efficient power generation under ambient lighting. *Nature Photonics* **11**, 372–378 (2017).



- Co-sensitized system \rightarrow higher photocurrent
- $\text{Cu}(\text{tmby})_2$ as redox mediator \rightarrow higher photovoltage

History and State of the Art

- 1980s sensitization of TiO_2
- 1991 Nature paper: $\eta = 7\%$
- Solid state DSC



- Now: $\eta = 13\%$
- Dye with designated (broad or IR) spectrum
- Electrolyte for high voltage

A low-cost, high-efficiency solar cell based on dye-sensitized colloidal TiO_2 films

Brian O'Regan* & Michael Grätzel†

Institute of Physical Chemistry, Swiss Federal Institute of Technology, CH-1015 Lausanne, Switzerland

THE large-scale use of photovoltaic devices for electricity generation is prohibitively expensive at present: generation from existing commercial devices costs about ten times more than conventional methods¹. Here we describe a photovoltaic cell, created from low-to medium-purity materials through low-cost processes, which exhibits a commercially realistic energy-conversion efficiency. The device is based on a 10- μm -thick, optically transparent film of titanium dioxide particles a few nanometres in size, coated with a monolayer of a charge-transfer dye to sensitize the film for light harvesting. Because of the high surface area of the semiconductor film and the ideal spectral characteristics of the dye, the device harvests a high proportion of the incident solar energy flux (46%) and shows exceptionally high efficiencies for the conversion of incident photons to electrical current (more than 80%). The overall light-to-electric energy conversion yield is 7.1–7.9% in simulated solar light and 12% in diffuse daylight. The large current densities (greater than 12 mA cm^{-2}) and exceptional stability (sustaining at least five million turnovers without decomposition), as well as the low cost, make practical applications feasible.

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† To whom correspondence should be addressed.

Applications



www.connect-green.com

- Consumer: Indoor, Internet of Things
- Building integrated
- Challenges: Efficiency, Stability